
**Silicon Photodetectors,
Optical Sensors and
Infrared Emitters**

**Si-Fotodetektoren,
Optische Sensoren und
IR-Lumineszenzdioden**

Silicon Photodetectors

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Detector/Emitter in Multi TOPLED® package	
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Plastic package with daylight blocking filter for 880/950 nm IRED	
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SmartLED®	
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Detector/Emitter in Multi TOPLED® package	
SMR	
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IR-Lumineszenzdiode

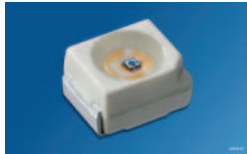
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Maßzeichnungen

Summary of Types | Typenübersicht

Phototransistors | Fototransistoren

SMT Transistors | SMT Transistoren



TOPLED®
SFH 320
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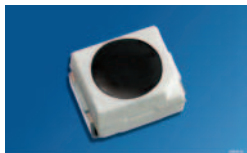
SIDELED®
SFH 325
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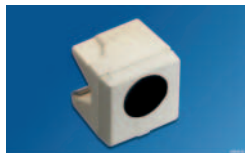
TOPLED® with Lens
SFH 3219
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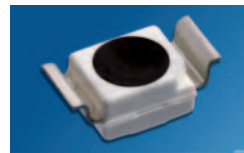
Multi TOPLED®
SFH 331 / SFH 7221 / SFH 7225
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TOPLED®
SFH 320 FA
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SIDELED®
SFH 325 FA
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TOPLED® RG
SFH 3211 FA
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MIDLED
SFH 3600
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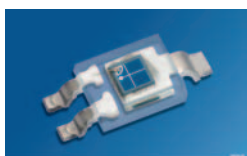
SFH 3605
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SmartLED® 0603
SFH 3010
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Micro SIDELED®
SFH 3204
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Smart DIL
SFH 3400 / SFH 3401
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Smart DIL
SFH 3410
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CHIPLED
SFH 3710
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SFH 3201
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Summary of Types | Typenübersicht

Phototransistors | Fototransistoren

Phototransistors in plastic package | Fototransistoren im Plastikgehäuse



SFH 309 / SFH 310
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SFH 309 P / SFH 3310
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SFH 300 / SFH 313 (not for new design) / SFH 314
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SFH 3500
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SFH 309 FA / SFH 310 FA
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SFH 309 PFA
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SFH 300 FA / SFH 313 FA / SFH 314FA
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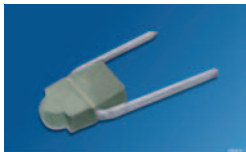
SFH 303 FA
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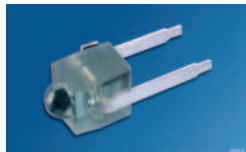
LPT 80 A
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SFH 3100 F
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SFH 305
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BPX 81
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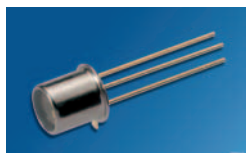


BPX 83
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Phototransistors in metal package | Fototransistoren im Metallgehäuse



BPY 62 / BPX 43
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BPX 38
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BP 103
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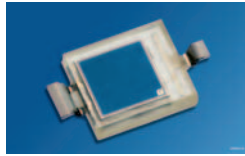
Summary of Types | Typenübersicht

Photodiodes | Fotodioden

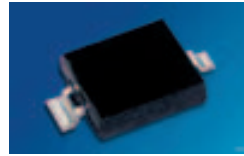
SMT PIN Photodiodes | SMT PIN Fotodioden



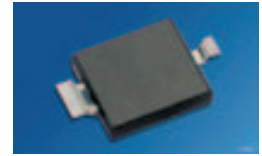
BP 104 S / BPW 34 S / BPW 34 BS
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BPW 34 SR / BP 104 SR
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BP 104 FS / BP 104 FAS / BPW 34 FS
/ BPW 34 FAS
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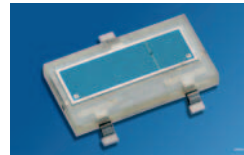
BPW 34 FSR / BPW 34 FASR / BP
104 FASR
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Smart DIL
SFH 2400
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SMR
SFH 2505
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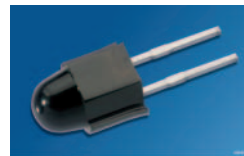
KOM 2125
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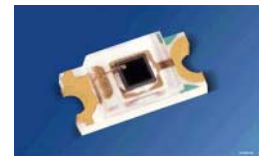
Smart DIL
SFH 2400 FA
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SMR
SFH 2500 FA
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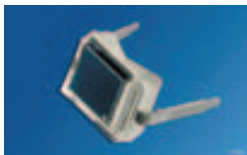


SMR
SFH 2505 FA
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SFH 2701
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PIN Photodiodes in plastic package | PIN Fotodioden im Plastikgehäuse



BPW 34 / BPW 34 B
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SFH 229 / SFH 2332 / SFH 2302
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SFH 203 / SFH 213
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BPW 34 F / BPW 34 FA / BP 104 F
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SFH 206 K
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SFH 229 FA
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SFH 203 FA / SFH 213 FA
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Summary of Types | Typenübersicht

Photodiodes | Fotodioden



SFH 203 P
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SFH 203 PFA
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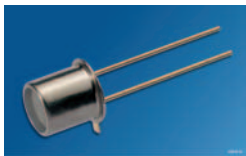


SFH 225 FA / SFH 235 FA
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SFH 205 F / SFH 205 FA
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PIN Photodiodes in metal package | PIN Fotodioden im Metallgehäuse



BPX 65
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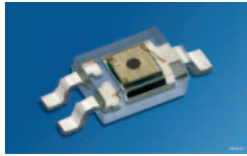


BPX 61
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Summary of Types | Typenübersicht

Photo ICs | Foto ICs

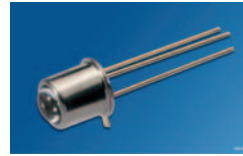
Schmitt Trigger



Smart DIL
SFH 5440
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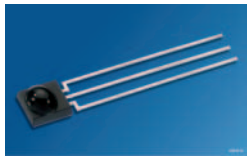


SFH 5140 F
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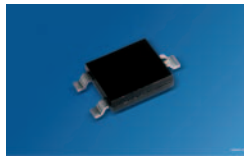


SFH 5840
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Photo IC for remote control | Foto IC für Fernsteuerung



SFH 5110
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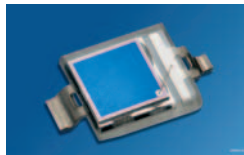


SFH 5410
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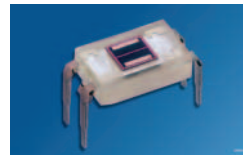
Photodetectors for special applications | Fotodetektoren für spezielle Anwendungen



BPW 34 B
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BPW 34 BS
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BPX 48
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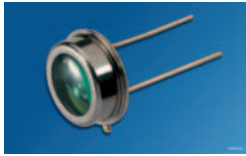


SFH 221
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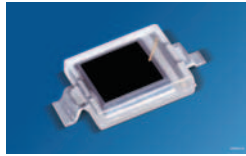
Summary of Types | Typenübersicht

Ambient Light Sensors | Umgebungslichtsensoren

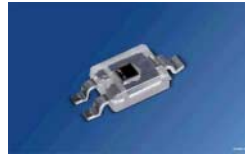
Ambient Light Sensors | Umgebungslichtsensoren



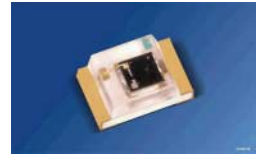
Photodiode
BPW 21
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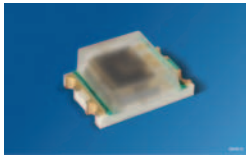
Photodiode
SFH 2430
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Phototransistor
SFH 3410
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Phototransistor
SFH 3710
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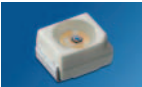
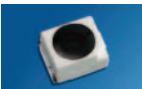

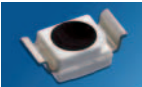






High Accuracy Ambient Light Sensor
SFH 5711
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Phototransistor
SFH 3310
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Phototransistors | Fototransistoren



Package Gehäuse	Type Bezeichnung	Half angle φ [°]	Radiant sensitive area typ. [mm ²]	IpCE	Measure- ment cond.	V _{CE} max.	λ _{10%} typ.	t _r , t _f typ	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				[μA]		[V]	[nm]	[μs]		
SMT Transistors SMT Transistoren										
 SmartLED® 0603	SFH 3010	± 80	0.04	≥ 25	λ = 950 nm, E _p = 0.5 mW/cm ² , V _{CE} = 5 V	15	420 ... 1100	7	Q65110A6458	51
 TOPLED®	SFH 320	± 60	0.038	16 ... 80	λ = 950 nm, E _p = 0.1 mW/cm ² , V _{CE} = 5 V	35	450 ... 1150	7	Q65110A2471	2
	SFH 320-3			25 ... 50				Q65110A2469		
	SFH 320-3/4			25 ... 80				Q65110A1781		
	SFH 320-4			40 ... 80				Q65110A2510		
 TOPLED®	SFH 320 FA	± 60	0.038	16 ... 80	λ = 950 nm, E _p = 0.1 mW/cm ² , V _{CE} = 5 V	35	750 ... 1120	7	Q65110A2472	2
	SFH 320 FA-3			25 ... 50				Q65110A2470		
	SFH 320 FA-3/4			25 ... 80				Q65110A2475		
	SFH 320 FA-4			40 ... 80				Q65110A1836		
 TOPLED® with Lens	SFH 3219	± 25	0.038	≥ 63	λ = 950 nm, E _p = 0.1 mW/cm ² , V _{CE} = 5 V	35	450 ... 1150	7	Q65110A2651	49
 TOPLED® RG	SFH 3211 FA	± 60	0.038	16 ... 80	λ = 950 nm, E _p = 0.1 mW/cm ² , V _{CE} = 5 V	35	750 ... 1120	7	Q65110A2526	3
	SFH 3211 FA-3/4			25 ... 80				7.5	Q65110A2528	
 SIDELED®	SFH 325	± 60	0.038	16 ... 80	λ = 950 nm, E _p = 0.1 mW/cm ² , V _{CE} = 5 V	35	450 ... 1150	7	Q65110A2486	4
	SFH 325-3			25 ... 50				Q65110A2488		
	SFH 325-3/4			25 ... 80				7.5	Q65110A2491	
	SFH 325-4			40 ... 80				8	Q65110A2484	
 SIDELED®	SFH 325 FA	± 60	0.038	16 ... 80	λ = 950 nm, E _p = 0.1 mW/cm ² , V _{CE} = 5 V	35	750 ... 1120	7	Q65110A2487	4
	SFH 325 FA-3			25 ... 50				Q65110A2482		
	SFH 325 FA-3/4			25 ... 80				7.5	Q65110A2490	
	SFH 325 FA-4			40 ... 80				8	Q65110A2485	
 Micro SIDE-LED®	SFH 3204	± 60	0.04	≥ 32	λ = 950 nm, E _p = 0.1 mW/cm ² , V _{CE} = 5 V	15	450 ... 1120	7	Q65110A2506	81
 SmartDIL	SFH 3400	± 60	0.55	63 ... 320	λ = 950 nm, E _p = 0.1 mW/cm ² , V _{CE} = 5 V	20	460 ... 1080	24	Q65110A2629	9
	SFH 3400-2/3			100 ... 320				29	Q65110A2634	

Silicon Photodetectors | Si-Fotodetektoren

Package Gehäuse	Type Bezeichnung	Half angle φ [°]	Radiant sensitive area typ. [mm ²]			V_{CE} max. [V]	$\lambda_{10\%}$ typ. [nm]	t_r, t_f typ [μs]	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				I_{PCE} [μA]	Measure- ment cond.					
 SmartDIL	SFH 3401	± 60	0.55	63 ... 320	$\lambda = 950 \text{ nm}, E_p = 0.1 \text{ mW/cm}^2, V_{CE} = 5 \text{ V}$	20	460 ... 1080	24	Q65110A2635	10
	SFH 3401-2/3			100 ... 320				29	Q65110A2644	
 SmartDIL	SFH 3201	± 60	0.55	63 ... 320	$\lambda = 950 \text{ nm}, E_p = 0.1 \text{ mW/cm}^2, V_{CE} = 5 \text{ V}$	20	460 ... 1080	24	Q65110A1207	11
	SFH 3201-2/3			100 ... 320				29	Q65110A2479	


Package Gehäuse	Type Bezeichnung	Half angle φ [°]	Radiant sensitive area typ. [mm ²]			V_{CE} max. [V]	$\lambda_{10\%}$ typ. [nm]	t_r, t_f typ [μs]	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				I_{PCE} [μA]	Measure- ment cond.					

SMT Transistors in low profile, narrow angle MIDLED package | SMT Transistoren in flachem, engwinkligem MIDLED Gehäuse

 MIDLED	SFH 3600	± 20	0.04	100 ... 500	$\lambda = 950 \text{ nm}, E_p = 0.1 \text{ mW/cm}^2, V_{CE} = 5 \text{ V}$	35	500 ... 1100	45	Q65110A1573	97
	SFH 3600-2/3			100 ... 320				37	Q65110A2665	
	SFH 3600-3/4			160 ... 500				57	Q65110A2666	
 MIDLED	SFH 3605	± 20	0.04	100 ... 500	$\lambda = 950 \text{ nm}, E_p = 0.1 \text{ mW/cm}^2, V_{CE} = 5 \text{ V}$	35	500 ... 1100	45	Q65110A1574	97
	SFH 3605-2/3			100 ... 320				37	Q65110A2663	
	SFH 3605-3/4			160 ... 500				57	Q65110A2664	

Package Gehäuse	Type Bezeichnung	Emitter Sender						Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
		λ_{peak} typ [nm]	Half angle φ [°]	I_V [mcd]	Measure- ment cond.	V_F [V]	Measure- ment cond.		


Detector/Emitter in Multi TOPLED® package | Empfänger/Sender im Multi TOPLED® Gehäuse

 Multi TOPLED®	SFH 331-JK	635	± 60	6 (4 ... 12.5)	I _F = 10 mA	2 (≤ 2.6)	I _F = 10 mA	Q65110A2821	5
Detector Empfänger									
		Radiant sensitive area typ. [mm ²]	I _{PCE} [μA]	Measure- ment cond.	V _{CE} max. [V]	λ _{10%} typ. [nm]	t _r , t _f typ [μs]		
		0.038	≥ 16	λ = 950 nm, E _e = 0.1 mW/ cm ² , V _{CE} = 5 V	35	380 ... 1150	7		

Silicon Photodetectors | Si-Fotodetektoren


Package Gehäuse	Type Bezeichnung	Emitter Sender						Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
		λ_{peak} typ [nm]	Half angle ϕ [°]	I_e [mW/sr]	Measure- ment cond.	V_F [V]	Measure- ment cond.		

Detector/Emitter in Multi TOPLED® package | Empfänger/Sender im Multi TOPLED® Gehäuse



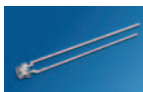




 Multi TOPLED®	SFH 7221	880	± 60	> 4	$I_F = 100 \text{ mA}$, $t_p = 20 \text{ ms}$	1.5 (≤ 1.8)	$I_F = 100 \text{ mA}$, $t_p = 20 \text{ ms}$	Q65110A2741	6
	Detector Empfänger								
		Radiant sensitive area typ. [mm ²]	I_{PCE} [μA]	Measure- ment cond.	V_{CE} max. [V]	$\lambda_{10\%}$ typ. [nm]	t_r, t_f typ [μs]		
		0.038	≥ 16	$\lambda = 880 \text{ nm}$, $E_e = 0.1 \text{ mW/cm}^2$, $V_{CE} = 5 \text{ V}$	35	380 ... 1150	7		

Package Gehäuse	Type Bezeichnung	Emitter Sender						Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
		λ_{peak} typ [nm]	Half angle ϕ [°]	I_v [mcd]	Measure- ment cond.	V_F [V]	Measure- ment cond.		









Detector/Emitter in Multi TOPLED® package | Empfänger/Sender im Multi TOPLED® Gehäuse

 Multi TOPLED®	SFH 7225	591	± 60	63 ... 200	$I_F = 20 \text{ mA}$	2	$I_F = 20 \text{ mA}$, $t_p = 20 \text{ ms}$	Q65110A2743	5
	Detector Empfänger								
		Radiant sensitive area typ. [mm ²]	I_{PCE} typ [μA]	Measure- ment cond.	V_{CE} max. [V]	Crosstalk $I_{PCE, \text{ typ}}$ [mA]	Measure- ment Con- ditions		
		0.038	650	Std. Light A, $E_v = 1000 \text{ lx}$, $V_{CE} = 5 \text{ V}$	35	0.5 ... 5	$I_F = 20 \text{ mA}$, $V_{CE} = 5 \text{ V}$		


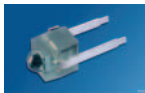

Silicon Photodetectors | Si-Fotodetektoren

Package Gehäuse	Type Bezeichnung	Half angle φ [°]	Radiant sensitive area typ. [mm ²]	IpCE	Measure- ment cond.	V _{CE} max. [V]	λ _{10%} typ. [nm]	t _r , t _f typ [μs]	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				[mA]						
Phototransistors in clear plastic package Fototransistoren im klaren Plastikgehäuse										
 T 1	SFH 309	± 12	0.038	0.4 ... 5	λ = 950 nm, E _p = 0.5 mW/cm ² , V _{CE} = 5 V	35	380 ... 1150	7	Q62702P0859	22
	SFH 309-3/4			0.63 ... 2				6.5	Q62702P3592	
	SFH 309-4			1 ... 2				7	Q62702P0998	
	SFH 309-4/5			1 ... 3.2				7.5	Q62702P3593	
	SFH 309-5			1.6 ... 3.2				8	Q62702P0999	
	SFH 309-5/6			1.6 ... 5				8.5	Q62702P3594	
 T 1	SFH 310	± 25	0.11	0.63 ... 3.2	λ = 950 nm, E _p = 0.5 mW/cm ² , V _{CE} = 5 V	70	450 ... 1100	9	Q62702P0874	23
	SFH 310-2/3			0.63 ... 2				7.5	Q62702P3595	
 T 1	SFH 309 P	± 75	0.038	≥ 0.063	λ = 950 nm, E _p = 0.5 mW/cm ² , V _{CE} = 5 V	35	380 ... 1180	6	Q62702P0245	24
 T 1 3/4	SFH 314	± 40	0.55	1 ... 3.2	λ = 950 nm, E _p = 0.5 mW/cm ² , V _{CE} = 5 V	70	460 ... 1080	11	Q62702P1668	26
	SFH 314-2/3								Q62702P3600	
 T 1 3/4	SFH 300	± 25	0.11	≥ 0.63	λ = 950 nm, E _p = 0.5 mW/cm ² , V _{CE} = 5 V	35	450 ... 1100	10	Q62702P1189	82
	SFH 300-3/4			≥ 1					Q62702P3586	
 T1 3/4 SMR	SFH 3500	± 13	0.55	4 ... 20	λ = 950 nm, E _p = 0.5 mW/cm ² , V _{CE} = 5 V	70	450 ... 1060	19	Q65110A2636	7
	SFH 3500-5/6			6.3 ... 20				22	Q65110A3458	
	LPT 80A	± 35	0.11	≥ 0.25	λ = 950 nm, E _p = 0.5 mW/cm ² , V _{CE} = 5 V	30	450 ... 1100	10	Q68000A7852	28





Silicon Photodetectors | Si-Fotodetektoren

Package Gehäuse	Type Bezeichnung	Half angle φ [°]	Radiant sensitive area typ. [mm ²]	I _{PCE}	Measure- ment cond.	V _{CE} max. [V]	λ _{10%} typ. [nm]	t _r , t _f typ	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				[mA]				[μs]		
Plastic package with daylight blocking filter for 880/950 nm IRED Plastikgehäuse mit Tageslichtsperrfilter für 880/950 nm IRED										
 T 1	SFH 309 FA SFH 309 FA-3/4 SFH 309 FA-4 SFH 309 FA-4/5 SFH 309 FA-5 SFH 309 FA-5/6	± 12	0.038	0.4 ... 5 0.63 ... 2 1 ... 2 1 ... 3.2 1.6 ... 3.2 1.6 ... 5	λ = 950 nm, E _P = 0.5 mW/cm ² , V _{CE} = 5 V	35	730 ... 1120	7 6.5 7 7.5 8 8.5	Q62702P0941 Q62702P3590 Q62702P0178 Q62702P3591 Q62702P0180 Q62702P5199	22
 T 1	SFH 310 FA SFH 310 FA-2/3	± 25	0.11	0.4 ... 3.2 0.63 ... 2	λ = 950 nm, E _P = 0.5 mW/cm ² , V _{CE} = 5 V	70	740 ... 1100	9 7.5	Q62702P1673 Q62702P3596	23
 T 1	SFH 309 PFA	± 75	0.038	≥ 0.063	λ = 950 nm, E _P = 0.5 mW/cm ² , V _{CE} = 5 V	35	730 ... 1120	6	Q62702P0246	24
 T 1 3/4	SFH 313 FA SFH 313 FA-2/3 SFH 313 FA-3/4	± 10	0.55	≥ 2.5 4 ... 12.5 ≥ 6.3	λ = 950 nm, E _P = 0.5 mW/cm ² , V _{CE} = 5 V	70	740 ... 1080	10 11 13	Q62702P1674 Q62702P3597 Q62702P5196	25
 T 1 3/4	SFH 314 FA SFH 314 FA-2/3	± 40	0.55	≥ 0.63 1 ... 3.2	λ = 950 nm, E _P = 0.5 mW/cm ² , V _{CE} = 5 V	70	740 ... 1080	11	Q62702P1675 Q62702P3599	26
 T 1 3/4	SFH 300 FA SFH 300 FA-3/4	± 25	0.11	≥ 0.63 ≥ 1	λ = 950 nm, E _P = 0.5 mW/cm ² , V _{CE} = 5 V	35	730 ... 1120	10	Q62702P1193 Q62702P3585	82
 T 1 3/4	SFH 303 FA SFH 303 FA-3/4	± 20	0.11	≥ 1 ≥ 1.6	λ = 950 nm, E _P = 0.5 mW/cm ² , V _{CE} = 5 V	35	750 ... 1120	13 14	Q62702P0958 Q62702P3587	27
 T 1 3/4	SFH 3100 F	± 14	0.11	0.4 ... 5	λ = 950 nm, E _P = 0.5 mW/cm ² , V _{CE} = 5 V	30	840 ... 1080	9	Q62702P5073	29


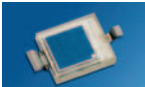

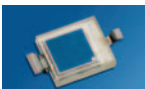




Silicon Photodetectors | Si-Fotodetektoren

Package Gehäuse	Type Bezeichnung	Half angle φ [°]	Radiant sensitive area typ. [mm ²]	l _{PCE}	Measure- ment cond.	V _{CE} max.	λ _{10%} typ.	t _r , t _f typ	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				[mA]		[V]	[nm]	[μs]		
Phototransistor Arrays in plastic package Fototransistor-Zeilen im Plastikgehäuse										
	SFH 305	± 16	0.11	0.25 ... 1.25	λ = 950 nm, E _p = 0.5 mW/cm ² , V _{CE} = 5 V	35	450 ... 1100	6	Q62702P0836	31
	SFH 305-2/3			0.25 ... 0.8					Q62702P3589	
	BPX 81	± 18	0.11	≥ 0.25	λ = 950 nm, E _p = 0.5 mW/cm ² , V _{CE} = 5 V	35	450 ... 1100	7	Q62702P0020	32
	BPX 81-2/3			0.25 ... 0.8					Q62702P3583	
	BPX 81-3			0.4 ... 0.8					Q62702P0043S0 03	
	BPX 81-3/4			≥ 0.4					Q62702P3584	
	BPX 81-4			≥ 0.63					Q62702P0043S0 04	
 Array	BPX 82	± 18	0.11	≥ 0.32	λ = 950 nm, E _p = 0.5 mW/cm ² , V _{CE} = 5 V	35	450 ... 1100	6	Q62702P0021	33
	BPX 83								Q62702P0025	
	BPX 84								Q62702P0030	
	BPX 85								Q62702P0031	
	BPX 86								Q62702P0022	
	BPX 87								Q62702P0032	
	BPX 88								Q62702P0033	
	BPX 89								Q62702P0026	
	BPX 80								Q62702P0028	

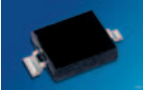
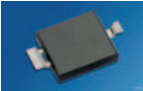

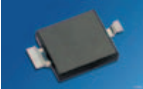


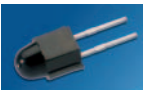
Silicon Photodetectors | Si-Fotodetektoren

Package Gehäuse	Type Bezeichnung	Half angle φ [°]	Radiant sensitive area typ. [mm ²]	I_{PCE} [mA]	Measure- ment cond.	V_{CE} max. [V]	$\lambda_{10\%}$ typ. [nm]	t_r, t_f typ [μs]	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
Phototransistors in metal package Fototransistoren im Metallgehäuse										
 TO-18	BPY 62	± 8	0.11	0.5 ... 4	$\lambda = 950 \text{ nm}, E_p = 0.5 \text{ mW/cm}^2, V_{CE} = 5 \text{ V}$	35	400 ... 1100	8	Q60215Y0062	30
	BPY 62-3			0.8 ... 1.6				7	Q60215Y1112	
	BPY 62-3/4			0.8 ... 2.5				8	Q62702P5198	
	BPY 62-4			1.25 ... 2.5				9	Q60215Y1113	
 TO 18	BPX 43	± 15	0.675	≥ 0.8	$\lambda = 950 \text{ nm}, E_p = 0.5 \text{ mW/cm}^2, V_{CE} = 5 \text{ V}$	50	450 ... 1100	14	Q62702P0016	30
	BPX 43-3/4			1.25 ... 4					Q62702P3581	
	BPX 43-4			2 ... 4				15	Q62702P0016S0 04	
	BPX 43-4/5			≥ 2				17	Q62702P3582	
	BPX 43-5			≥ 3.2				18	Q62702P0016S0 05	
 TO 18	BPX 38	± 40	0.675	≥ 0.2	$\lambda = 950 \text{ nm}, E_p = 0.5 \text{ mW/cm}^2, V_{CE} = 5 \text{ V}$	50	450 ... 1120	12	Q62702P0015	67
	BPX 38-2/3			0.2 ... 0.63				11	Q62702P3578	
	BPX 38-3			0.32 ... 0.63				12	Q62702P0015S0 03	
	BPX 38-4			0.5 ... 1				15	Q62702P0015S0 04	
 TO 18	BP 103	± 55	0.11	≥ 0.08	$\lambda = 950 \text{ nm}, E_p = 0.5 \text{ mW/cm}^2, V_{CE} = 5 \text{ V}$	35	450 ... 1100	8	Q62702P0075	68
	BP 103-3/4			0.125 ... 0.4					Q62702P3577	

Photodiodes | Fotodioden

Package Gehäuse	Type Bezeichnung	Half angle φ ±	Radi- ant sen- sitive area typ.	I _P	Measu- re-ment cond.	I _R	Measu- re-ment cond.	λ _{10%} typ.	t _r , t _f typ	Measure- ment cond.	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
SMT PIN Photodiodes in clear package SMT PIN Fotodioden in klarem Gehäuse												
 SMT DIL	BP 104 S	± 60	4.84	55 (≥ 40)	E _v = 1000 lx, Std. Light A, V _R = 5 V	2 (≤ 30)	V _R = 10 V	400 ... 1100	0.02	V _R = 5 V; R _L = 50 Ω; λ = 850 nm; I _p = 800 μA	Q65110A2626	13
 SMT DIL	BP 104 SR	± 60	4.84	55 (≥ 40)	E _v = 1000 lx, Std. Light A, V _R = 5 V	2 (≤ 30)	V _R = 10 V	400 ... 1100	0.02	V _R = 5 V; R _L = 50 Ω; λ = 850 nm; I _p = 800 μA	Q65110A4262	15
 SMT DIL	BPW 34 S	± 60	7.02	80 (≥ 50)	E _v = 1000 lx, Std. Light A, V _R = 5 V	2 (≤ 30)	V _R = 10 V	400 ... 1100	0.02	V _R = 5 V; R _L = 50 Ω; λ = 850 nm; I _p = 800 μA	Q65110A1209	14
 SMT DIL	BPW 34 SR	± 60	7.02	80 (≥ 50)	E _v = 1000 lx, Std. Light A, V _R = 5 V	2 (≤ 30)	V _R = 10 V	400 ... 1100	0.02	V _R = 5 V; R _L = 50 Ω; λ = 850 nm; I _p = 800 μA	Q65110A2701	15
 SMT DIL	BPW 34 BS	± 60	7.45	75	E _v = 1000 lx, Std. Light A, V _R = 5 V	2 (≤ 30)	V _R = 10 V	350 ... 1100	0.025	V _R = 5 V; R _L = 50 Ω; λ = 850 nm; I _p = 800 μA	Q65110A2625	14
 SmartDIL	SFH 2400	± 60	1.00	10 (≥ 6)	E _v = 1000 lx, Std. Light A, V _R = 5 V	1 (≤ 5)	V _R = 20 V	400 ... 1100	0.005	V _R = 20 V; R _L = 50 Ω; λ = 850 nm; I _p = 800 μA	Q65110A2628	16
 T1 3/4 SMR	SFH 2505	± 15	1.00	100	E _v = 1000 lx, Std. Light A, V _R = 5 V	1 (≤ 5)	V _R = 20 V	400 ... 1100	0.005	V _R = 20 V; R _L = 50 Ω; λ = 850 nm; I _p = 800 μA	Q65110A1203	8
	SFH 2701	± 60	0.36	1.4	780nm, V _R = 5 V, 0,5mW/cm ²	0.05 (≤ 5)	V _R = 5 V	400 ... 1050	0.002	V _R = 5 V; R _L = 50 Ω; λ = 780 nm; I _p = 1 mA	Q65110A2960	95

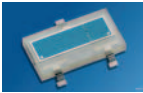
Silicon Photodetectors | Si-Fotodetektoren

Package Gehäuse	Type Bezeichnung	Half angle $\varphi \pm$ [°]	Radi- ant sen- sitive area typ. [mm ²]	I_P [μA]	Meas- urement cond.	I_R [nA]	Meas- urement cond.	$\lambda_{10\%}$ typ. [nm]	t_r, t_f typ [μs]	Measure- ment cond.	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
SMT PIN Photodiodes with daylight blocking filter SMT PIN Fotodiode mit Tageslichtsperrfilter												
 SMT DIL	BP 104 FS	± 60	4.84	34 (≥ 25)	$\lambda = 950$ nm, $E_g = 1$ mW/cm ² , $V_R = 5$ V	2 (≤ 30)	$V_R = 10$ V	780 ... 1100	0.02	$V_R = 5$ V; $R_L = 50 \Omega$; $\lambda = 850$ nm; $I_p = 800 \mu A$	Q65110A2627	13
	BP 104 FAS				$\lambda = 870$ nm, $E_g = 1$ mW/cm ² , $V_R = 5$ V			730 ... 1100			Q65110A2672	
 SMT DIL	BP 104 FASR	± 60	4.84	34 (≥ 25)	$\lambda = 870$ nm, $E_g = 1$ mW/cm ² , $V_R = 5$ V	2 (≤ 30)	$V_R = 10$ V	730 ... 1100	0.02	$V_R = 5$ V; $R_L = 50 \Omega$; $\lambda = 850$ nm; $I_p = 800 \mu A$	Q65110A4263	21
 SMT DIL	BPW 34 FS	± 60	7.02	50 (≥ 40)	$\lambda = 950$ nm, $E_g = 1$ mW/cm ² , $V_R = 5$ V	2 (≤ 30)	$V_R = 10$ V	780 ... 1100	0.02	$V_R = 5$ V; $R_L = 50 \Omega$; $\lambda = 850$ nm; $I_p = 800 \mu A$	Q65110A2700	14
	BPW 34 FAS				$\lambda = 870$ nm, $E_g = 1$ mW/cm ² , $V_R = 5$ V			730 ... 1100			Q65110A3121	
 SMT DIL	BPW 34 FSR	± 60	7.02	50 (≥ 40)	$\lambda = 950$ nm, $E_g = 1$ mW/cm ² , $V_R = 5$ V	2 (≤ 30)	$V_R = 10$ V	780 ... 1100	0.02	$V_R = 5$ V; $R_L = 50 \Omega$; $\lambda = 850$ nm; $I_p = 800 \mu A$	Q65110A2740	15
	BPW 34 FASR				$\lambda = 870$ nm, $E_g = 1$ mW/cm ² , $V_R = 5$ V			730 ... 1100			Q65110A2699	
 Smart DIL	SFH 2400 FA	± 60	1.00	6.2 (≥ 3.6)	$\lambda = 870$ nm, $E_g = 1$ mW/cm ² , $V_R = 5$ V	1 (≤ 5)	$V_R = 20$ V	750 ... 1100	0.005	$V_R = 20$ V; $R_L = 50 \Omega$; $\lambda = 850$ nm; $I_p = 800 \mu A$	Q65110A2638	16
 T1 3/4 SMR	SFH 2500 FA	± 15	1.00	70 (≥ 50)	$\lambda = 870$ nm, $E_g = 1$ mW/cm ² , $V_R = 5$ V	1 (≤ 5)	$V_R = 20$ V	750 ... 1100	0.005	$V_R = 20$ V; $R_L = 50 \Omega$; $\lambda = 850$ nm; $I_p = 800 \mu A$	Q65110A1202	7
 T1 3/4 SMR	SFH 2505 FA	± 15	1.00	70 (≥ 50)	$\lambda = 870$ nm, $E_g = 1$ mW/cm ² , $V_R = 5$ V	1 (≤ 5)	$V_R = 20$ V	750 ... 1100	0.005	$V_R = 20$ V; $R_L = 50 \Omega$; $\lambda = 850$ nm; $I_p = 800 \mu A$	Q65110A1204	8

Silicon Photodetectors | Si-Fotodetektoren

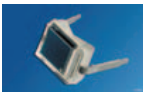
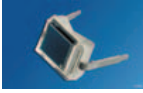





Package Gehäuse	Type Bezeichnung	Half angle $\varphi \pm$ [°]	Radiant sensitive area typ. [mm ²]	I _P		Measur- ement cond.		$\lambda_{10\%}$ typ. [nm]	t _r , t _f typ [μs]		Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				[μA]		[nA]						

SMT Dual Photodiodes | SMT Doppelfotodioden

	KOM 2125	± 60	4 diode A 10 diode B	40 (≥ 30) diode A 10 (≥ 75) diode B	E _v = 1000 lx, Std. Light A, V _R = 5 V	5 (≤ 30) diode A 10 (≤ 30) diode B	V _R = 10 V	400 ... 1100	0.025	V _R = 5 V; R _L = 50 Ω; λ = 850 nm; I _p = 800 μA	Q65110A2703	17
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Package Gehäuse	Type Bezeichnung	Half angle $\varphi \pm$ [°]	Radi- ant sen- sitive area typ. [mm ²]	I _P		Measur- ement cond.		$\lambda_{10\%}$ typ. [nm]	t _r , t _f typ [μs]		Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				[μA]		[nA]						



PIN Photodiodes in clear plastic package | PIN Fotodioden in klarem Plastikgehäuse

 DIL	BPW 34	± 60	7.02	80 (≥ 50)	E _v = 1000 lx, Std. Light A, V _R = 5 V	2 (≤ 30)	V _R = 10 V	400 ... 1100	0.02	V _R = 5 V; R _L = 50 Ω; λ = 850 nm; I _p = 800 μA	Q62702P0073	84
 DIL	BPW 34 B	± 60	7.45	75	E _v = 1000 lx, Std. Light A, V _R = 5 V	2 (≤ 30)	V _R = 10 V	350 ... 1100	0.025	V _R = 5 V; R _L = 50 Ω; λ = 850 nm; I _p = 800 μA	Q65110A3126	84
 TO-92	SFH 206 K	± 60	7.02	80 (≥ 50)	E _v = 1000 lx, Std. Light A, V _R = 5 V	2 (≤ 30)	V _R = 10 V	400 ... 1100	0.02	V _R = 5 V; R _L = 50 Ω; λ = 850 nm; I _p = 800 μA	Q62702P0129	35
 T 1	SFH 229	± 17	0.31	28 (≥ 18)	E _v = 1000 lx, Std. Light A, V _R = 5 V	0.05 (≤ 5)	V _R = 10 V	380 ... 1100	0.01	V _R = 10 V; R _L = 50 Ω; λ = 850 nm; I _p = 800 μA	Q62702P0215	22
 T 1 3/4	SFH 203	± 20	1.00	80 (≥ 50)	E _v = 1000 lx, Std. Light A, V _R = 5 V	1 (≤ 5)	V _R = 20 V	400 ... 1100	0.005	V _R = 20 V; R _L = 50 Ω; λ = 850 nm; I _p = 800 μA	Q62702P0955	36
 T 1 3/4	SFH 213	± 10	1.00	135 (≥ 100)	E _v = 1000 lx, Std. Light A, V _R = 5 V	1 (≤ 5)	V _R = 20 V	400 ... 1100	0.005	V _R = 20 V; R _L = 50 Ω; λ = 850 nm; I _p = 800 μA	Q62702P0930	25
 T 1 3/4	SFH 203 P	± 75	1.00	9.5 (≥ 5)	E _v = 1000 lx, Std. Light A, V _R = 5 V	1 (≤ 5)	V _R = 20 V	400 ... 1100	0.005	V _R = 20 V; R _L = 50 Ω; λ = 850 nm; I _p = 800 μA	Q62702P0942	37

Silicon Photodetectors | Si-Fotodetektoren







Package Gehäuse	Type Bezeichnung	Half angle $\varphi \pm$ [°]	Radi- ant sen- sitive area typ. [mm ²]	Meas- urement cond.		Meas- urement cond.	$\lambda_{10\%}$ typ. [nm]	Measure- ment cond.		Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				I_P [μA]		I_R [nA]		t_r, t_f typ [μs]			

PIN Photodiodes in clear plastic package | PIN Fotodioden in klarem Plastikgehäuse



 T 1	SFH 2302	± 17	0.36	≥ 10	$\lambda = 780$ nm, $E_g = 0.5$ mW/cm ² , $V_R = 5$ V	0.05 (≤ 5)	$V_R = 5$ V	400 ... 1050	0.002	$V_R = 5$ V; $R_L = 50$ Ω; $\lambda = 780$ nm; $I_p = 1$ mA	Q65110A6343	22
 T 1	SFH 2332	± 17	0.36	≥ 4.5	$\lambda = 405$ nm, $E_g = 0.5$ mW/cm ² , $V_R = 5$ V	0.035 (≤ 5)	$V_R = 10$ V	350 ... 1050	0.002	$V_R = 10$ V; $R_L = 50$ Ω; $\lambda = 405$ nm; $I_p = 1$ mA	Q65110A6342	22

Package Gehäuse	Type Bezeichnung	Half angle $\varphi \pm$ [°]	Radi- ant sen- sitive area typ. [mm ²]	Meas- urement cond.		Meas- urement cond.	$\lambda_{10\%}$ typ. [nm]	Measure- ment cond.		Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				I_P [μA]		I_R [nA]		t_r, t_f typ [μs]			

PIN Photodiodes with daylight filter matched for 880 nm IRED | PIN Fotodioden mit Tageslichtfilter für 880 nm IRED




 DIL	BPW 34 FA	± 60	7.02	50 (≥ 40)	$\lambda = 870$ nm, $E_g = 1$ mW/cm ² , $V_R = 5$ V	2 (≤ 30)	$V_R = 10$ V	730 ... 1100	0.02	$V_R = 5$ V; $R_L = 50$ Ω; $\lambda = 850$ nm; $I_p = 800$ μA	Q62702P1129	84
 TO-92	SFH 225 FA	± 60	4.84	34 (≥ 25)	$\lambda = 870$ nm, $E_g = 1$ mW/cm ² , $V_R = 5$ V	2 (≤ 30)	$V_R = 10$ V	740 ... 1120	0.02	$V_R = 5$ V; $R_L = 50$ Ω; $\lambda = 850$ nm; $I_p = 800$ μA	Q62702P1051	38
 TO-92	SFH 235 FA	± 65	7.02	50 (≥ 40)	$\lambda = 870$ nm, $E_g = 1$ mW/cm ² , $V_R = 5$ V	2 (≤ 30)	$V_R = 10$ V	740 ... 1120	0.02	$V_R = 5$ V; $R_L = 50$ Ω; $\lambda = 850$ nm; $I_p = 800$ μA	Q62702P0273	38
 TO-92	SFH 205 FA	± 60	7.02	60 (≥ 45)	$\lambda = 870$ nm, $E_g = 1$ mW/cm ² , $V_R = 5$ V	2 (≤ 30)	$V_R = 10$ V	740 ... 1100	0.02	$V_R = 5$ V; $R_L = 50$ Ω; $\lambda = 850$ nm; $I_p = 800$ μA	Q62702P1677	39
 T 1	SFH 229 FA	± 17	0.31	20 (≥ 10.8)	$\lambda = 950$ nm, $E_g = 1$ mW/cm ² , $V_R = 5$ V	0.05 (≤ 5)	$V_R = 10$ V	730 ... 1100	0.01	$V_R = 10$ V; $R_L = 50$ Ω; $\lambda = 850$ nm; $I_p = 800$ μA	Q62702P0216	22
 T 1 3/4	SFH 203 FA	± 20	1.00	50 (≥ 30)	$\lambda = 870$ nm, $E_g = 1$ mW/cm ² , $V_R = 5$ V	1 (≤ 5)	$V_R = 20$ V	800 ... 1100	0.005	$V_R = 20$ V; $R_L = 50$ Ω; $\lambda = 850$ nm; $I_p = 800$ μA	Q62702P0956	36

Silicon Photodetectors | Si-Fotodetektoren

Package Gehäuse	Type Bezeichnung	Half angle $\varphi \pm$ [°]	Radi- ant sen- sitive area typ. [mm ²]	Meas- urement cond.		Meas- urement cond.		$\lambda_{10\%}$ typ. [nm]	Meas- urement cond.		Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				I_P [μA]		I_R [nA]			t_r, t_f typ [μs]			
 T 1 3/4	SFH 213 FA	± 10	1.00	90 (≥ 65)	$\lambda = 870$ nm, $E_g = 1$ mW/cm ² , $V_R = 5$ V	1 (≤ 5)	$V_R = 20$ V	750 ... 1100	0.005	$V_R = 20$ V; $R_L = 50 \Omega$; $\lambda = 850$ nm; $I_p = 800 \mu A$	Q62702P1671	25
 T 1 3/4	SFH 203 PFA	± 75	1.00	6.2 (≥ 3.6)	$\lambda = 870$ nm, $E_g = 1$ mW/cm ² , $V_R = 5$ V	1 (≤ 5)	$V_R = 20$ V	750 ... 1100	0.005	$V_R = 20$ V; $R_L = 50 \Omega$; $\lambda = 850$ nm; $I_p = 800 \mu A$	Q62702P0947	37

Package Gehäuse	Type Bezeichnung	Half angle $\varphi \pm$ [°]	Radi- ant sen- sitive area typ. [mm ²]	Meas- urement cond.		Meas- urement cond.		$\lambda_{10\%}$ typ. [nm]	Meas- urement cond.		Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				I_P [μA]		I_R [nA]			t_r, t_f typ [μs]			

PIN Photodiodes with daylight filter matched for 950 nm IRED | PIN Fotodioden mit Tageslichtfilter für 950 nm IRED

 DIL	BP 104 F	± 60	4.84	34 (≥ 25)	$\lambda = 950$ nm, $E_g = 1$ mW/cm ² , $V_R = 5$ V	2 (≤ 30)	$V_R = 10$ V	800 ... 1100	0.02	$V_R = 5$ V; $R_L = 50 \Omega$; $\lambda = 850$ nm; $I_p = 800 \mu A$	Q62702P0084	41
 DIL	BPW 34 F	± 60	7.02	50 (≥ 40)	$\lambda = 950$ nm, $E_g = 1$ mW/cm ² , $V_R = 5$ V	2 (≤ 30)	$V_R = 10$ V	780 ... 1100	0.02	$V_R = 5$ V; $R_L = 50 \Omega$; $\lambda = 850$ nm; $I_p = 800 \mu A$	Q62702P0929	84
 TO-92	SFH 205 F	± 60	7.02	60 (≥ 45)	$\lambda = 950$ nm, $E_g = 1$ mW/cm ² , $V_R = 5$ V	2 (≤ 30)	$V_R = 10$ V	800 ... 1100	0.02	$V_R = 5$ V; $R_L = 50 \Omega$; $\lambda = 850$ nm; $I_p = 800 \mu A$	Q62702P0102	39

Package Gehäuse	Type Bezeichnung	Half angle $\varphi \pm$ [°]	Radi- ant sen- sitive area typ. [mm ²]	Meas- urement cond.		Meas- urement cond.		$\lambda_{10\%}$ typ. [nm]	Meas- urement cond.		Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				I_P [μA]		I_R [nA]			t_r, t_f typ [μs]			

PIN Photodiodes in metal package | PIN Fotodioden im Metallgehäuse



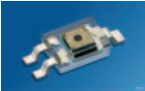


 TO 18	BPX 65	± 40	1.00	10 (≥ 5.5)	$E_v = 1000$ lx, Std. Light A, $V_R = 5$ V	1 (≤ 5)	$V_R = 20$ V	350 ... 1100	0.012	$V_R = 5$ V; $R_L = 50 \Omega$; $\lambda = 850$ nm; $I_p = 800 \mu A$	Q62702P0027	43
	BPX 61	± 55	7.02	70 (≥ 50)	$E_v = 1000$ lx, Std. Light A, $V_R = 5$ V	2 (≤ 30)	$V_R = 10$ V	400 ... 1100	0.02	$V_R = 5$ V; $R_L = 50 \Omega$; $\lambda = 850$ nm; $I_p = 800 \mu A$	Q62705P0025	44

Photo ICs | Foto ICs


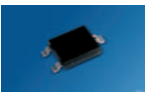
Package Gehäuse	Type Bezeichnung	Half angle φ [°]	V_{CC} [V]	$E_{e \text{ typ}}$	Measure- ment cond.	$\lambda_{10\% \text{ typ.}}$ [nm]	$I_{OUT \text{ max}}$ [mA]	t_{PLH} [μs]	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				[mW/m ²]						

Schmitt Trigger

	SFH 5440	± 60	4 ... 18	+1700 (≤ +3200)	$V_{CC} = 5V, \lambda = 950 \text{ nm}$	400 ... 1100	16	5 (≤ 15)	Q65110A1212	18
	SFH 5140 F	± 12	4 ... 18	+150 (≤ +500)	$V_{CC} = 5V, \lambda = 950 \text{ nm}$	840 ... 1080	16	5 (≤ 15)	Q62702P5112	19
	SFH 5840	± 5	4 ... 18	+100 (≤ +320)	$V_{CC} = 5V, \lambda = 950 \text{ nm}$	400 ... 1100	16	5 (≤ 15)	Q62702P5116	20

Package Gehäuse	Type Bezeichnung	f_0	Half angle φ [°]	$E_{e \text{ typ}}$ [mW/m ²]	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
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Photo IC for remote control | Foto IC für Fernsteuerung

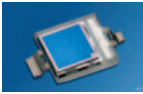
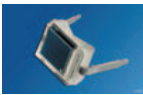

	SFH 5110-30	30	h.: ± 50, v.: ± 30	0.35 (≤ 0.5)	Q62702P5088	1
	SFH 5110-33	33			Q62702P5089	
	SFH 5110-36	36			Q62702P5090	
	SFH 5110-38	38			Q62702P5091	
	SFH 5110-40	40			Q62702P5092	
	SFH 5410-36	36	± 60	1.4 (≤ 2.0)	Q65110A1727	78
	SFH 5410-38	38			Q65110A3909	

SMT DIL

Photodetectors for special applications | Fotodetektoren für spezielle Anwendungen


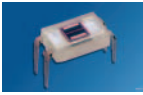
Package Gehäuse	Type Bezeichnung	Half angle φ [°]	Radi- ant sensi- tive area typ. [mm ²]	Measu- ment cond.		I_R [nA]	Measu- ment cond.	$\lambda_{10\%}$ typ. [nm]	t_r, t_f typ [μs]	Measu- ment cond.	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				I_{SC} [μA]								

Blue sensitive photodiode | Blauempfindliche Fotodiode

 SMT DIL	BPW 34 BS	± 60	7.45	7.4 (≥ 5.4)	$E_e = 0.5 \text{ mW/cm}^2, \lambda = 400 \text{ nm}$	2 (≤ 30)	$V_R = 10 \text{ V}$	350 ... 1100	0.025	$V_R = 5 \text{ V}; R_L = 50 \text{ Ω}; \lambda = 850 \text{ nm}; I_p = 800 \text{ μA}$	Q65110A2625	14
 DIL	BPW 34 B	± 60	7.45	7.4 (≥ 5.4)	$E_e = 0.5 \text{ mW/cm}^2, \lambda = 400 \text{ nm}$	2 (≤ 30)	$V_R = 10 \text{ V}$	350 ... 1100	0.025	$V_R = 5 \text{ V}; R_L = 50 \text{ Ω}; \lambda = 850 \text{ nm}; I_p = 800 \text{ μA}$	Q65110A3126	84
 T 1	SFH 2332	± 17	0.36	-	-	0.035 (≤ 5)	$V_R = 10 \text{ V}$	350 ... 1050	0.002	$V_R = 10 \text{ V}; R_L = 50 \text{ Ω}; \lambda = 405 \text{ nm}; I_p = 1 \text{ mA}$	Q65110A6342	22

Package Gehäuse	Type Bezeichnung	Half angle φ [°]	Radi- ant sensi- tive area typ. [mm ²]	Measu- ment cond.		I_R [nA]	Measu- ment cond.	$\lambda_{10\%}$ typ. [nm]	t_r, t_f typ [μs]	Measu- ment cond.	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				I_p [μA]								


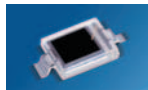
Dual photodiodes | Doppelfotodioden

	SFH 221	± 55	1.54	24 (≥ 15)	$E_v = 1000 \text{ lx, Std. Light A, } V_R = 5 \text{ V}$	10 (≤ 100)	$V_R = 10 \text{ V}$	400 ... 1100	0.5	$V_R = 5 \text{ V}; R_L = 1 \text{ kΩ}; \lambda = 850 \text{ nm}; I_p = 20 \text{ μA}$	Q62702P0270	45
	BPX 48	± 60	1.54	24 (≥ 15)	$E_v = 1000 \text{ lx, Std. Light A, } V_R = 5 \text{ V}$	10 (≤ 100)	$V_R = 10 \text{ V}$	400 ... 1150	0.5	$V_R = 5 \text{ V}; R_L = 1 \text{ kΩ}; \lambda = 850 \text{ nm}; I_p = 20 \text{ μA}$	Q62702P0017S0 01	46

Ambient Light Sensors | Umgebungslichtsensoren

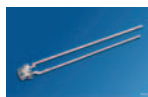


Package Gehäuse	Type Bezeichnung	Half angle φ	Radiant sensitive area typ.					$\lambda_{10\%}$ typ.	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				I_P	Measure- ment cond.	I_R	Measure- ment cond.			
		[°]	[mm ²]	[μA]		[nA]		[nm]		

Photodiode Ambient Light Sensors | Fotodiode, Umgebungslichtsensor

	BPW 21	± 55	7.45	10 (≥ 5.5)	$E_v = 1000$ lx, Std. Light A, V_R = 5 V	2 (≤ 30)	$V_R = 5$ V	350 ... 820	Q62702P0885	44
 SMT DIL	SFH 2430	± 60	7.02	5.8 (≥ 4)	$E_v = 1000$ lx, Std. Light A, V_R = 5 V	0.1 (≤ 5)	$V_R = 5$ V	400 ... 900	Q65110A2673	83

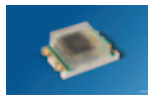
Package Gehäuse	Type Bezeichnung	Half angle φ	Radiant sensitive area typ.			V_{CE} max.	$\lambda_{10\%}$ typ.	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				I_{PCE}	Measure- ment cond.				
		[°]	[mm ²]	[μA]		[V]	[nm]		

Phototransistor Ambient Light Sensors | Fototransistor, Umgebungslichtsensor

 T 1	SFH 3310	± 75	0.29	2.5 ... 8	$\lambda = 560$ nm, E_e = 10 μW/cm ² , $V_{CE} = 5$ V	5.5	350 ... 970	Q65110A5343	24
	SFH 3410	± 60	0.29	3.2 ... 25	Std. Light A, $E_v = 20$ lx, V_{CE} = 5V	5.5	350 ... 970	Q65110A1211	12
	SFH 3410-1/2			3.2 ... 10				Q65110A2653	
	SFH 3410-2/3			5 ... 16				Q65110A2654	
	SFH 3410-3/4			8 ... 25				Q65110A2655	
	SFH 3710	± 60	0.29	2.5 ... 12.5	$\lambda = 560$ nm, E_e = 10 μW/cm ² , $V_{CE} = 5$ V	5.5	350 ... 950	Q65110A3107	90
	SFH 3710-2/3			2.5 ... 8				Q65110A3512	
	SFH 3710-3/4			4 ... 12.5				Q65110A3511	

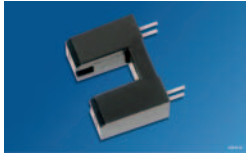
Package Gehäuse	Type Bezeichnung	Half angle φ	Radiant sensi- tive area typ.			$\lambda_{10\%}$ typ.	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				I_{OUT}	Measurement Conditions			
		[°]	[mm ²]	[mA]		[nm]		

High Accuracy Ambient Light Sensors | Hochgenauer Umgebungslichtsensor

	SFH 5711-2/3	± 60	0.16	0.027 ... 0.032	Std. Light A, $E_v =$ 1000 lx, $V_{CE} = 5$ V	475 ... 650	Q65110A4513	91
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Summary of Types | Typenübersicht

Slotted Interrupters | Gabellichtschranken

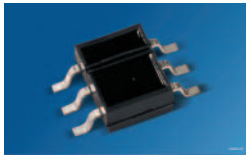


SFH 9315
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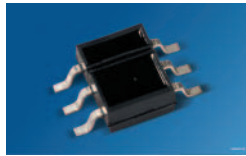


SFH 9500
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SMT Reflective Sensors | SMT Reflexlichtschranken

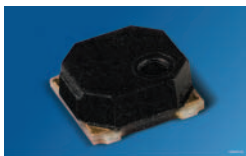


SFH 9201 / SFH 9202
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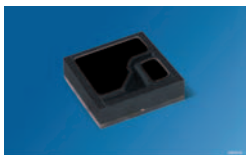
Schmitt Trigger
SFH 9240
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SMT Orientation Sensor | SMT Kippsensor



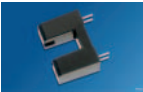

SFH 7710
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SMT Proximity Sensor | SMT Näherungssensor





SFH 7740 / SFH7741
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Slotted Interrupters | Gabellichtschranken

Package Gehäuse	Type Bezeichnung	Features	Slot Width [mm]	Aperture slit width on emitter / sensor side typ [mm]	I_{PCE} min [μA]	I_{CE0}	Measure- ment cond.	V_F [V]	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
						[nA]				
	SFH 9315	horizontal slits	5	0.5 / 0.5	700	1 (≤ 50)	$V_{CE} = 20 \text{ V}$	1.2 (≤ 1.4)	Q65110A1216	47
	SFH 9500	with vertical aperture slits, SMT version, suitable for reflow soldering, locating pins	5	0.5 / 0.5	1000	1 (≤ 50)	$V_{CE} = 20 \text{ V}$	1.2 (≤ 1.4)	Q65110A3108	98


SMT Reflective Sensors | SMT Reflexlichtschranken

Package Gehäuse	Type Bezeichnung	I_{PCE}	Measure- ment cond.	I_{CE0}	Measure- ment cond.	V_{CE} max.	V_F	Measure- ment cond.	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
		[μA]				[V]	[V]			
	SFH 9201	250 ... 2000	Kodak neu- tral white testcard with 90% reflection, $V_{CE} = 5 \text{ V}$, $d = 1 \text{ mm}$, $I_F = 10 \text{ mA}$	3 (≤ 200)	$V_{CE} = 20 \text{ V}$, $E = 0$	16	1.25 (≤ 1.65)	$I_F = 50 \text{ mA}$	Q65110A2708	48
	SFH 9201-2/3	400 ... 1250							Q65110A2698	
	SFH 9201-3/4	630 ... 2000							Q65110A2716	
	SFH 9202	63 ... 800	Kodak neu- tral white testcard with 90% reflection, $V_{CE} = 5 \text{ V}$, $d = 1 \text{ mm}$, $I_F = 10 \text{ mA}$	1 (≤ 50)	$V_{CE} = 20 \text{ V}$	16	1.25 (≤ 1.65)	$I_F = 50 \text{ mA}$	Q65110A2712	48
	SFH 9202-2/3	63 ... 200							Q65110A2705	
	SFH 9202-3/4	100 ... 320							Q65110A2710	
	SFH 9202-4/5	160 ... 500							Q65110A2709	
	SFH 9202-5/6	250 ... 800							Q65110A2711	

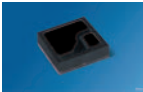
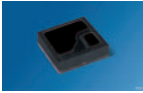
Schmitt Trigger

Package Gehäuse	Type Bezeichnung	Features	V_{CC} [V]	$I_{F, ON}$	Measurement cond.	$E_{e, off} /$ $E_{e, on}$	V_F [V]	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				[mA]					
	SFH 9240	Schmitt Trigger Output, active "low"	4 ... 18	3 (< 10)	Kodak neutral white testcard with 90% reflection, $V_{CC} = 5 \text{ V}$, $d = 1 \text{ mm}$	0.6 (0.5 ... 0.9)	1.25 (≤ 1.65)	Q65110A2714	48

SMT Orientation Sensor | SMT Kippsensor

Package Gehäuse	Type Bezeichnung	V _{out} at horizontal position	V _{out} at vertical position	V _{cc} [V]	I _{DD} typ [mA]	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
	SFH 7710	low	high	2.3 ... 3.6	0.023	Q65110A4407	96
	SFH 7710 R33					Q65110A6819	

SMT Proximity Sensor | SMT Näherungssensor

Package Gehäuse	Type Bezeichnung	Working distance typ [mm]	V _{cc} [V]	max. Sink Current [mA]	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
	SFH 7740	0.5 ... 4	2.3 ... 3.6	10	Q65110A6668	76
	SFH 7741	0.5 ... 20	2.3 ... 3.6	10	Q65110A7073	76

Summary of Types | Typenübersicht

SMT Emitters | SMT Emitter



Golden DRAGON®
SFH 4230 / SFH 4231
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MIDLED
SFH 4600 / SFH 4650 / SFH 4680
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MIDLED
SFH 4605 / SFH 4655 / SFH 4685
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SmartLED® 0603
SFH 4010 / SFH 4050 / SFH 4080
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TOPLED®
SFH 420 / SFH 4211 / SFH 421 / SFH 4200 / SFH 4252
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SIDELED®
SFH 425 / SFH 426 / SFH 4205 / SFH 4255
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TOPLED®
SFH 4257 / SFH 4271 / SFH 4272 / SFH 4273
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TOPLED® RG
SFH 4281
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Mini TOPLED®
SFH 4203
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TOPLED® with Lens
SFH 4209 / SFH 4289
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Multi TOPLED®
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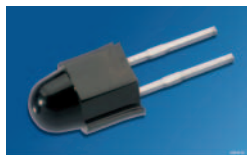
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SMR
SFH 4500 / SFH 4510
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SMR
SFH 4505 / SFH 4515
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Summary of Types | Typenübersicht

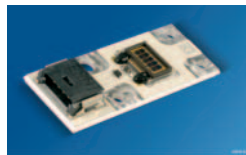
SMT Emitters | SMT Emitter



Power TOPLED®
SFH 4250
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Power TOPLED® with Lens
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OSTAR® Observation
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OSTAR® Observation
SFH 4740
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High power emitters 850 nm | Hochleistungsemitter 850 nm



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Power TOPLED®
SFH 4250
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Power TOPLED® with Lens
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MIDLED
SFH 4650
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MIDLED
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Golden DRAGON®
SFH 4230 / SFH 4231
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Summary of Types | Typenübersicht

High speed emitters 950 nm | Sehr schnelle Emitter 950 nm



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MIDLED
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MIDLED
SFH 4605
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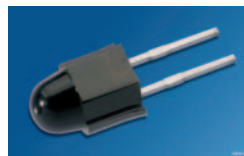
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Summary of Types | Typenübersicht

Emitters in plastic package | Emitter im Plastikgehäuse



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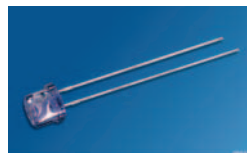
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Summary of Types | Typenübersicht

Emitters in metal package | Emitter im Metallgehäuse



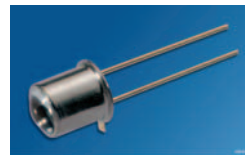
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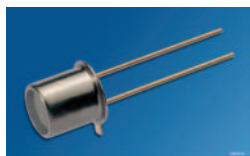
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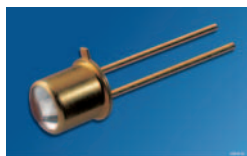
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SMT Emitters | SMT Emitter



Package Gehäuse	Type Bezeichnung	λ_{peak} typ [nm]	Half angle φ [°]	Φ_e typ [mW]		V_F [V]	Measure- ment cond.	t_r, t_f typ [ns]	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung

Golden DRAGON®

 Golden DRA- GON®	SFH 4230	850	± 60	440	$I_F = 1 \text{ A}, t_p = 100 \mu\text{s}$	1.8 (≤ 2.4)	$I_F = 1 \text{ A}, t_p = 100 \mu\text{s}$	10	Q65110A4023	92
	SFH 4231	940	± 60	500	$I_F = 1 \text{ A}, t_p = 100 \mu\text{s}$	1.8 (≤ 2.4)	$I_F = 1 \text{ A}, t_p = 100 \mu\text{s}$	20	Q65110A4808	92


Package Gehäuse	Type Bezeichnung	λ_{peak} typ [nm]	Half angle φ [°]	I_e [mW/sr]		V_F [V]	Measure- ment cond.	t_r, t_f typ [ns]	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung

MIDLED



 MIDLED	SFH 4600	950	± 20	30 (> 16)	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	1.5 (≤ 1.8)	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	10	Q65110A1575	97
	SFH 4680	880		20 (> 10)				500	Q65110A1570	
	SFH 4650	850		40 (> 16)				12	Q65110A1572	
 MIDLED	SFH 4605	950	± 20	30 (> 16)	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	1.5 (≤ 1.8)	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	10	Q65110A1576	97
	SFH 4685	880		20 (> 10)				500	Q65110A1571	
	SFH 4655	850		40 (> 16)				12	Q65110A1569	

Package Gehäuse	Type Bezeichnung	λ_{peak} typ [nm]	Half angle φ [°]	I_e [mW/sr]		V_F [V]	Measure- ment cond.	t_r, t_f typ [ns]	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung

SmartLED®







 SmartLED® 0603	SFH 4010	950	± 80	2.5 (> 1)	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	1.3 (≤ 1.5)	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	500	Q65110A6459	51
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Infrared Emitters | IR-Lumineszenzdioden








Package Gehäuse	Type Bezeichnung	λ_{peak} typ [nm]	Half angle φ [°]					t_r, t_f typ [ns]	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				I_e [mW/sr]	Measure- ment cond.	V_F [V]	Measure- ment cond.			
 SmartLED®	SFH 4080	880	± 80	2.5 (> 1)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.8)	$I_F = 100$ mA, $t_p = 20$ ms	500	Q65110A6461	51
 SmartLED® 0603	SFH 4050	850	± 80	7 (> 4)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.8)	$I_F = 100$ mA, $t_p = 20$ ms	12	Q65110A6460	51

Package Gehäuse	Type Bezeichnung	λ_{peak} typ [nm]	Half angle φ [°]					t_r, t_f typ [ns]	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				I_e [mW/sr]	Measure- ment cond.	V_F [V]	Measure- ment cond.			

TOPLED®/SIDELED® Family | TOPLED®/SIDELED® Familie

 TOPLED®	SFH 420	950	± 60	5 (> 2.5)	$I_F = 100$ mA, $t_p = 20$ ms	1.3 (≤ 1.5)	$I_F = 100$ mA, $t_p = 20$ ms	500	Q65110A2473	79
 SIDELED®	SFH 425	950	± 60	5 (> 2.5)	$I_F = 100$ mA, $t_p = 20$ ms	1.3 (≤ 1.5)	$I_F = 100$ mA, $t_p = 20$ ms	500	Q65110A2463	71
 TOPLED®	SFH 421	880	± 60	7 (> 4)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.8)	$I_F = 100$ mA, $t_p = 20$ ms	500	Q65110A1218	79
 SIDELED®	SFH 426	880	± 60	7 (> 4)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.8)	$I_F = 100$ mA, $t_p = 20$ ms	500	Q65110A2512	71
 TOPLED®	SFH 4252	850	± 60	16 (> 10)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.9)	$I_F = 100$ mA, $t_p = 20$ ms	12	Q65110A2468	79
 TOPLED®	SFH 4200	950	± 60	10 (> 4)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.8)	$I_F = 100$ mA, $t_p = 20$ ms	10	Q65110A2494	79





Infrared Emitters | IR-Lumineszenzdioden

Package Gehäuse	Type Bezeichnung	λ_{peak} typ [nm]	Half angle φ [°]					t_r, t_f typ [ns]	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				I_e [mW/sr]	Measure- ment cond.	V_F [V]	Measure- ment cond.			
 SIDELED®	SFH 4205	950	± 60	10 (> 4)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.8)	$I_F = 100$ mA, $t_p = 20$ ms	10	Q65110A2498	71
 SIDELED®	SFH 4255	850	± 60	15 (> 10)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.9)	$I_F = 100$ mA, $t_p = 20$ ms	12	Q65110A2467	71
 TOPLED®	SFH 4211	950	± 60	6 (> 2.5)	$I_F = 100$ mA, $t_p = 20$ ms	1.3 (≤ 1.5)	$I_F = 100$ mA, $t_p = 20$ ms	500	Q65110A2515	79
 TOPLED® RG	SFH 4281	880	± 60	4 ... 12.5	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.8)	$I_F = 100$ mA, $t_p = 20$ ms	500	Q65110A2516	70
 Mini TOPLED®	SFH 4203	950	± 65	8 (> 4)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.8)	$I_F = 100$ mA, $t_p = 20$ ms	10	Q65110A2499	50
 Power TOPLED®	SFH 4250	850	± 60	15 (> 10)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.9)	$I_F = 100$ mA, $t_p = 20$ ms	12	Q65110A2465	72
 TOPLED®	SFH 4257	850	± 60	7 (> 4)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.9)	$I_F = 100$ mA, $t_p = 20$ ms	12	Q65110A2466	80
	SFH 4271	880		2 (> 1)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.8)	$I_F = 100$ mA, $t_p = 20$ ms	500	Q65110A2521	
	SFH 4272	645		0.35 (> 0.16)	$I_F = 20$ mA, $t_p = 20$ ms	2 (≤ 2.5)	$I_F = 20$ mA, $t_p = 20$ ms		Q65110A2522	79
	SFH 4273	660		1 (> 0.63)	$I_F = 50$ mA, $t_p = 20$ ms	2.1 (≤ 2.8)	$I_F = 50$ mA, $t_p = 20$ ms	100	Q65110A2523	

Infrared Emitters | IR-Lumineszenzdioden


Package Gehäuse	Type Bezeichnung	λ_{peak} typ [nm]	Half angle φ [°]					t_r, t_f typ [ns]	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				I_e [mW/sr]	Measure- ment cond.	V_F [V]	Measure- ment cond.			

TOPLED®/SIDELED® Family | TOPLED®/SIDELED® Familie

 TOPLED® with Lens	SFH 4209	950	± 25	24 (> 10)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.8)	$I_F = 100$ mA, $t_p = 20$ ms	10	Q65110A2501	49
 TOPLED® with Lens	SFH 4289	880	± 25	17 (> 6.3)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.8)	$I_F = 100$ mA, $t_p = 20$ ms	500	Q65110A2519	49
 Power TOPLED® w. Lens	SFH 4259	850	± 25	55 (> 25)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.8)	$I_F = 100$ mA, $t_p = 20$ ms	12	Q65110A2464	73
 Power TOPLED® w. Lens	SFH 4258	850	± 15	90 (> 40)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.8)	$I_F = 100$ mA, $t_p = 20$ ms	12	Q65110A2975	85

Package Gehäuse	Type Bezeichnung	λ_{peak} typ [nm]	Half angle φ [°]					t_r, t_f typ [ns]	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				I_e [mW/sr]	Measure- ment cond.	V_F [V]	Measure- ment cond.			


TOPLED®/SIDELED® Family | TOPLED®/SIDELED® Familie

 SIDELED®	SFH 425	950	± 60	5 (> 2.5)	I _F = 100 mA, t _p = 20 ms	1.3 (≤ 1.5)	I _F = 100 mA, t _p = 20 ms	500	Q65110A2463	71
	SFH 4205			10 (> 4)		1.5 (≤ 1.8)		10	Q65110A2498	
	SFH 426			7 (> 4)		500		Q65110A2512		
	SFH 4255	850		15 (> 10)		1.5 (≤ 1.9)		12	Q65110A2467	

Infrared Emitters | IR-Lumineszenzdiode


Package Gehäuse	Type Bezeichnung	λ_{peak} typ [nm]	Half angle φ [°]					t_r, t_f typ [ns]	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				I_e [mW/sr]	Measure- ment cond.	V_F [V]	Measure- ment cond.			

2 Emitters in Multi TOPLED® Package | 2 Sender in Multi TOPLED® Package

 Multi TOPLED®	SFH 7222	880	± 60	> 4	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.8)	$I_F = 100$ mA, $t_p = 20$ ms	500	Q65110A2742	54
		565				2.0 (≤ 2.6)	$I_F = 10$ mA, $t_p = 20$ ms	450		

Package Gehäuse	Type Bezeichnung	Emitter Sender						Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
		λ_{peak} typ [nm]	Half angle φ [°]	I_V [mcd]	Measure- ment cond.	V_F [V]	Measure- ment cond.		


Detector/Emitter in Multi TOPLED® package | Empfänger/Sender im Multi TOPLED® Gehäuse

 Multi TOPLED®	SFH 331-JK	635	± 60	6 (4 ... 12.5)	I _F = 10 mA	2 (≤ 2.6)	I _F = 10 mA	Q65110A2821	5
Detector Empfänger									
Radiant sensitive area typ. [mm ²]		I _{PCE} [μA]	Measure- ment cond.	V _{CE} max. [V]	λ _{10%} typ. [nm]	t _r , t _f typ [μs]			
0.038		≥ 16	λ = 950 nm, E _e = 0.1 mW/ cm ² , V _{CE} = 5 V	35	380 ... 1150	7			

Infrared Emitters | IR-Lumineszenzdioden


Package Gehäuse	Type Bezeichnung	Emitter Sender						Ordering Code Bestellnummer	Package Fig. Bauteilzeichnung
		λ_{peak} typ [nm]	Half angle ϕ [°]	I_e [mW/sr]	Measure-ment cond.	V_F [V]	Measure-ment cond.		

Detector/Emitter in Multi TOPLED® package | Empfänger/Sender im Multi TOPLED® Gehäuse




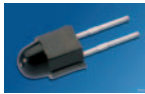
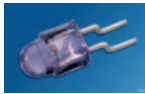

 Multi TOPLED®	SFH 7221	880	± 60	> 4	$I_F = 100 \text{ mA}$, $t_p = 20 \text{ ms}$	1.5 (≤ 1.8)	$I_F = 100 \text{ mA}$, $t_p = 20 \text{ ms}$	Q65110A2741	6
	Detector Empfänger								
		Radiant sensitive area typ. [mm ²]	I_{PCE} [µA]	Measure-ment cond.	V_{CE} max. [V]	$\lambda_{10\%}$ typ. [nm]	t_r, t_f typ [µs]		
		0.038	≥ 16	$\lambda = 880 \text{ nm}$, $E_e = 0.1 \text{ mW/cm}^2$, $V_{CE} = 5 \text{ V}$	35	380 ... 1150	7		

Package Gehäuse	Type Bezeichnung	Emitter Sender						Ordering Code Bestellnummer	Package Fig. Bauteilzeichnung
		λ_{peak} typ [nm]	Half angle ϕ [°]	I_v [mcd]	Measure-ment cond.	V_F [V]	Measure-ment cond.		

Detector/Emitter in Multi TOPLED® package | Empfänger/Sender im Multi TOPLED® Gehäuse



 Multi TOPLED®	SFH 7225	591	± 60	63 ... 200	$I_F = 20 \text{ mA}$	2	$I_F = 20 \text{ mA}$, $t_p = 20 \text{ ms}$	Q65110A2743	5
	Detector Empfänger								
		Radiant sensitive area typ. [mm ²]	I_{PCE} typ [µA]	Measure-ment cond.	V_{CE} max. [V]	Crosstalk $I_{PCE, \text{ typ}}$ [mA]	Measure-ment Con- ditions		
		0.038	650	Std. Light A, $E_v = 1000 \text{ lx}$, $V_{CE} = 5 \text{ V}$	35	0.5 ... 5	$I_F = 20 \text{ mA}$, $V_{CE} = 5 \text{ V}$		

Infrared Emitters | IR-Lumineszenzdioden

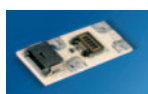

Package Gehäuse	Type Bezeichnung	λ_{peak} typ	Half angle φ		Measure- ment cond.		Measure- ment cond.	t_r, t_f typ	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
		[nm]		[°]		I_e		[mW/sr]		
SMR										
	SFH 4500	950	± 10	85 (> 25)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.8)	$I_F = 100$ mA, $t_p = 20$ ms	10	Q65110A2642	52
T1 3/4 SMR										
	SFH 4510	950	± 14	50 (> 25)	$I_F = 100$ mA, $t_p = 20$ ms	1.3 (≤ 1.5)	$I_F = 100$ mA, $t_p = 20$ ms	500	Q65110A2630	7
T1 3/4 SMR										
	SFH 4505	950	± 10	85 (> 25)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.8)	$I_F = 100$ mA, $t_p = 20$ ms	10	Q65110A2643	53
T1 3/4 SMR										
	SFH 4515	950	± 14	50 (> 25)	$I_F = 100$ mA, $t_p = 20$ ms	1.3 (≤ 1.5)	$I_F = 100$ mA, $t_p = 20$ ms	500	Q65110A2633	8
T1 3/4 SMR										
	SFH 4580	880	± 15	55 (> 25)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.8)	$I_F = 100$ mA, $t_p = 20$ ms	600	Q65110A2632	52
T1 3/4 SMR										
	SFH 4585	880	± 15	55 (> 25)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.8)	$I_F = 100$ mA, $t_p = 20$ ms	600	Q65110A2631	53
T1 3/4 SMR										

High power emitters for illumination | Hochleistungsemitter für Beleuchtung




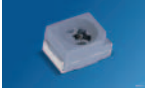




Package Gehäuse	Type Bezeichnung	λ_{peak} typ [nm]	Half angle φ [°]	Φ_e typ	Measure- ment cond.	V_F	Measure- ment cond.	t_r, t_f typ [ns]	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				[mW]		[V]				

 Golden DRAGON®	SFH 4230	850	± 60	440	$I_F = 1 \text{ A}, t_p = 100 \mu\text{s}$	1.8 (≤ 2.4)	$I_F = 1 \text{ A}, t_p = 100 \mu\text{s}$	10	Q65110A4023	92
 Golden DRAGON®	SFH 4231	940	± 60	500	$I_F = 1 \text{ A}, t_p = 100 \mu\text{s}$	1.8 (≤ 2.4)	$I_F = 1 \text{ A}, t_p = 100 \mu\text{s}$	20	Q65110A4808	92






Package Gehäuse	Type Bezeichnung	λ_{peak} typ [nm]	Half angle φ [°]	I_e typ	Measure- ment cond.	V_F	Measure- ment cond.	t_r, t_f typ [ns]	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				[mW / sr]		[V]				

 OSTAR® Observation	SFH 4730	850	± 60	1000	$I_F = 1 \text{ A}, t_p = 20 \text{ ms}$	18 (≤ 24)	$I_F = 1 \text{ A}, t_p = 100 \mu\text{s}$	10	Q65110A5452	99
 OSTAR® Observation	SFH 4740	850	± 60	1200	$I_F = 1 \text{ A}, t_p = 20 \text{ ms}$	18 (≤ 24)	$I_F = 1 \text{ A}, t_p = 100 \mu\text{s}$	10	Q65110A6190	99










High power emitters 850 nm | Hochleistungsemitter 850 nm

Package Gehäuse	Type Bezeichnung	λ_{peak} typ [nm]	Half angle φ [°]					t_r, t_f typ [ns]	Ordering Code Bestellnummer	Package Fig. Bauteilzeichnung
				I_e [mW/sr]	Measure- ment cond.	V_F [V]	Measure- ment cond.			
 SmartLED® 0603	SFH 4050	850	± 80	7 (> 4)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.9)	$I_F = 100$ mA, $t_p = 20$ ms	12	Q65110A6460	51
 Golden DRA- GON®	SFH 4230	850	± 60	170	$I_F = 1$ A, t_p $= 100 \mu\text{s}$	1.8 (≤ 2.4)	$I_F = 1$ A, t_p $= 100 \mu\text{s}$	10	Q65110A4023	92
 Power TOPLED®	SFH 4250	850	± 60	15 (> 10)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.9)	$I_F = 100$ mA, $t_p = 20$ ms	12	Q65110A2465	72
 TOPLED®	SFH 4257	850	± 60	7 (> 4)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.9)	$I_F = 100$ mA, $t_p = 20$ ms	12	Q65110A2466	80
 Power TOPLED® w. Lens	SFH 4259	850	± 25	55 (> 25)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.9)	$I_F = 100$ mA, $t_p = 20$ ms	12	Q65110A2464	73
 Power TOPLED® w. Lens	SFH 4258	850	± 15	90 (> 40)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.9)	$I_F = 100$ mA, $t_p = 20$ ms	12	Q65110A2975	85
 SIDELED®	SFH 4255	850	± 60	15 (> 10)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.9)	$I_F = 100$ mA, $t_p = 20$ ms	12	Q65110A2467	71
 MIDLED	SFH 4650	850	± 20	40 (> 16)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.9)	$I_F = 100$ mA, $t_p = 20$ ms	12	Q65110A1572	97


Infrared Emitters | IR-Lumineszenzdioden

Package Gehäuse	Type Bezeichnung	λ_{peak} typ [nm]	Half angle φ [°]					t_r, t_f typ [ns]	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				I_e [mW/sr]	Measure- ment cond.	V_F [V]	Measure- ment cond.			
 MIDLED	SFH 4655	850	± 20	40 (> 16)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.9)	$I_F = 100$ mA, $t_p = 20$ ms	12	Q65110A1569	97
 T 1 3/4	SFH 4550	850	± 3	700 (> 400)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.9)	$I_F = 100$ mA, $t_p = 20$ ms	12	Q65110A1772	60
 T 1 3/4	SFH 4556	850	± 20	130 (> 40)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.9)	$I_F = 100$ mA, $t_p = 20$ ms	12	Q65110A6087	100
 T 1	SFH 4350	850	± 13	70 (> 40)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.9)	$I_F = 100$ mA, $t_p = 20$ ms	12	Q65110A2091	86
 TO 18	SFH 4850 E7800	850	± 23	7 (> 4)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.9)	$I_F = 100$ mA, $t_p = 20$ ms	12	Q65110A2093	34

High speed emitters 950 nm | Sehr schnelle Emittter 950 nm

Package Gehäuse	Type Bezeichnung	λ_{peak} typ [nm]	Half angle ϕ [°]					t_r, t_f typ [ns]	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				I_e [mW/sr]	Measure- ment cond.	V_F [V]	Measure- ment cond.			
 TOPLED®	SFH 4200	950	± 60	10 (> 4)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.8)	$I_F = 100$ mA, $t_p = 20$ ms	10	Q65110A2494	79
 TOPLED® with Lens	SFH 4209	950	± 25	24 (> 10)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.8)	$I_F = 100$ mA, $t_p = 20$ ms	10	Q65110A2501	49
 SIDELED®	SFH 4205	950	± 60	10 (> 4)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.8)	$I_F = 100$ mA, $t_p = 20$ ms	10	Q65110A2498	71
 MIDLED	SFH 4600	950	± 20	30 (> 16)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.8)	$I_F = 100$ mA, $t_p = 20$ ms	10	Q65110A1575	97
 MIDLED	SFH 4605	950	± 20	30 (> 16)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.8)	$I_F = 100$ mA, $t_p = 20$ ms	10	Q65110A1576	97
 Mini TOPLED®	SFH 4203	950	± 65	8 (> 4)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.8)	$I_F = 100$ mA, $t_p = 20$ ms	10	Q65110A2499	50
 T1 3/4 SMR	SFH 4500	950	± 10	85 (> 25)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.8)	$I_F = 100$ mA, $t_p = 20$ ms	10	Q65110A2642	52
 T1 3/4 SMR	SFH 4505	950	± 10	85 (> 25)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.8)	$I_F = 100$ mA, $t_p = 20$ ms	10	Q65110A2643	53
 T 1	SFH 4301	950	± 10	75 (> 16)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.8)	$I_F = 100$ mA, $t_p = 20$ ms	10	Q62702P5166	55








Infrared Emitters | IR-Lumineszenzdioden

Package Gehäuse	Type Bezeichnung	λ_{peak} typ [nm]	Half angle φ [°]	I_e	Measure- ment cond.	V_F	Measure- ment cond.	t_r, t_f typ [ns]	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				[mW/sr]		[V]				
 T 1 3/4	SFH 4501	950	± 7	110 (> 63)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.8)	$I_F = 100$ mA, $t_p = 20$ ms	10	Q62702P5061	56
	SFH 4502		± 18	60 (> 25)					Q62702P5062	57
	SFH 4503		± 4	250 (> 63)					Q62702P5305	58




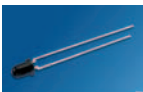






Emitters in plastic package | Emitter im Plastikgehäuse

Package Gehäuse	Type Bezeichnung	λ_{peak} typ [nm]	Half angle φ [°]	I_e	Measure- ment cond.	V_F	Measure- ment cond.	t_r, t_f typ [ns]	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				[mW/sr]		[V]				

Radial packages | Radiale Gehäuse

 T 1 3/4	SFH 4550	850	± 3	700 (> 400)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.9)	$I_F = 100$ mA, $t_p = 20$ ms	12	Q65110A1772	60
 T 1 3/4	SFH 4556	850	± 20	130 (> 40)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.9)	$I_F = 100$ mA, $t_p = 20$ ms	12	Q65110A6087	100
 T 1	SFH 4350	850	± 13	70 (> 40)	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.9)	$I_F = 100$ mA, $t_p = 20$ ms	12	Q65110A2091	86
 T 1 3/4	SFH 484	880	± 8	> 50	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.8)	$I_F = 100$ mA, $t_p = 20$ ms	600	Q62703Q1092	60
	SFH 484-2			> 80					Q62703Q1756	
 T 1 3/4	SFH 486	880	± 11	> 40	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.8)	$I_F = 100$ mA, $t_p = 20$ ms	600	Q62703Q1094	62
 T 1 3/4	SFH 485	880	± 20	25 ... 160	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.8)	$I_F = 100$ mA, $t_p = 20$ ms	600	Q62703Q1093	61
	SFH 485-2			25 ... 100					Q62703Q1547	
 T 1	SFH 487	880	± 20	> 12.5	$I_F = 100$ mA, $t_p = 20$ ms	1.5 (≤ 1.8)	$I_F = 100$ mA, $t_p = 20$ ms	600	Q62703Q1095	55
	SFH 487-2			20 ... 80					Q62703Q2174	
	SFH 487-3			32 ... 125					Q62703Q2175	




Infrared Emitters | IR-Lumineszenzdioden

Package Gehäuse	Type Bezeichnung	λ_{peak} typ [nm]	Half angle φ [°]	Measurement cond.		Measurement cond.		t_r, t_f typ [ns]	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				I_e [mW/sr]		V_F [V]				
 T 1 3/4	SFH 485 P	880	± 40	> 3.15	$I_F = 100$ mA, $t_p = 20$ ms	$1.5 (\leq 1.8)$	$I_F = 100$ mA, $t_p = 20$ ms	600	Q62703Q0516	63
 T 1	SFH 487 P	880	± 65	> 2	$I_F = 100$ mA, $t_p = 20$ ms	$1.5 (\leq 1.8)$	$I_F = 100$ mA, $t_p = 20$ ms	600	Q62703Q0517	64
 T 1 3/4	LD 274	950	± 10	> 50	$I_F = 100$ mA, $t_p = 20$ ms	$1.3 (\leq 1.5)$	$I_F = 100$ mA, $t_p = 20$ ms	500	Q62703Q1031	65
	LD 274-3			> 80					Q62703Q1820	
 T 1	SFH 4301	950	± 10	$75 (> 16)$	$I_F = 100$ mA, $t_p = 20$ ms	$1.5 (\leq 1.8)$	$I_F = 100$ mA, $t_p = 20$ ms	10	Q62702P5166	55
 T 1 3/4	SFH 4501	950	± 7	$110 (> 63)$	$I_F = 100$ mA, $t_p = 20$ ms	$1.5 (\leq 1.8)$	$I_F = 100$ mA, $t_p = 20$ ms	10	Q62702P5061	56
	SFH 4502		± 18	$60 (> 25)$					Q62702P5062	57
	SFH 4503		± 4	$250 (> 63)$					Q62702P5305	58
 T 1 3/4	LD 271	950	± 25	$15 (> 10)$	$I_F = 100$ mA, $t_p = 20$ ms	$1.3 (\leq 1.5)$	$I_F = 100$ mA, $t_p = 20$ ms	1000	Q62703Q0148	93
	LD 271-H			> 16					Q62703Q0256	
 T 1 3/4	LD 271 L	950	± 25	$15 (> 10)$	$I_F = 100$ mA, $t_p = 20$ ms	$1.3 (\leq 1.5)$	$I_F = 100$ mA, $t_p = 20$ ms	1000	Q62703Q0833	36
	LD 271 L-H			> 16					Q62703Q0838	
 T 1 3/4	SFH 415	950	± 17	> 25	$I_F = 100$ mA, $t_p = 20$ ms	$1.3 (\leq 1.5)$	$I_F = 100$ mA, $t_p = 20$ ms	500	Q62702P0296	36
	SFH 415 U			> 40					Q62702P1137	
 T 1 3/4	SFH 4511	950	± 4	$150 (> 63)$	$I_F = 100$ mA, $t_p = 20$ ms	$1.3 (\leq 1.5)$	$I_F = 100$ mA, $t_p = 20$ ms	500	Q62702P5557	87
 T 1	SFH 409	950	± 20	> 6.3	$I_F = 100$ mA, $t_p = 20$ ms	$1.3 (\leq 1.5)$	$I_F = 100$ mA, $t_p = 20$ ms	500	Q62702P0860	88
	SFH 409-2			> 10					Q62702P1002	

Infrared Emitters | IR-Lumineszenzdioden




Package Gehäuse	Type Bezeichnung	λ_{peak} typ [nm]	Half angle φ [°]					t_r, t_f typ [ns]	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				I_e [mW/sr]	Measure- ment cond.	V_F [V]	Measure- ment cond.			

Sidelooker







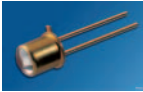


	IRL 81A	880	± 25	> 1	$I_F = 20$ mA, $t_p = 20$ ms	$1.5 (\leq 1.8)$	$I_F = 100$ mA, $t_p = 20$ ms	600	Q68000A8000	59
	IRL 80A	950	± 30	> 0.4	$I_F = 20$ mA, $t_p = 20$ ms	$1.2 (\leq 1.5)$	$I_F = 20$ mA	1000	Q68000A7851	59
	SFH 4110	950	± 9	> 2.5	$I_F = 20$ mA, $t_p = 20$ ms	$1.2 (\leq 1.4)$	$I_F = 20$ mA, $t_p = 20$ ms	450	Q62702P5072	29

Package Gehäuse	Type Bezeichnung	λ_{peak} typ [nm]	Half angle φ [°]					t_r, t_f typ [ns]	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				I_e [mW/sr]	Measure- ment cond.	V_F [V]	Measure- ment cond.			





Arrays in plastic package | Zeilen im Plastikgehäuse

	LD 261	950	± 15	2 ... 10	$I_F = 50$ mA, $t_p = 20$ ms	$1.25 (\leq 1.4)$	$I_F = 50$ mA, $t_p = 20$ ms	1000	Q62703Q0395	32
	LD 261-5/6			3.2 ... 10					Q65110A3337	
 Array	LD 262	950	± 15	5 (2 ... 6.3)	$I_F = 50$ mA, $t_p = 20$ ms	$1.25 (\leq 1.4)$	$I_F = 50$ mA, $t_p = 20$ ms	1000	Q62703Q0070	33
	LD 263								Q62703Q0071	
	LD 264								Q62703Q0072	
	LD 265								Q62703Q0073	
	LD 266								Q62703Q0074	
	LD 267								Q62703Q0075	
	LD 268								Q62703Q0076	
	LD 269								Q62703Q0077	
	LD 260								Q62703Q0078	
	SFH 405	950	± 16	$2.5 (> 1.6)$	$I_F = 40$ mA, $t_p = 20$ ms	$1.3 (\leq 1.5)$	$I_F = 100$ mA, $t_p = 20$ ms	1000	Q62702P0835	31

Emitters in metal package | Emitter im Metallgehäuse

Package Gehäuse	Type Bezeichnung	λ_{peak} typ [nm]	Half angle ϕ [°]					t_r, t_f typ [ns]	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				I_e [mW/sr]	Measure- ment cond.	V_F [V]	Measure- ment cond.			
 TO 18	SFH 464 E7800	660	± 23	> 1	$I_F = 50$ mA, $t_p = 20$ ms	$2.1 (\leq 2.8)$	$I_F = 50$ mA, $t_p = 20$ ms	100	Q62702P1745	34
 TO 18	SFH 4860	660	± 50	> 0.63	$I_F = 50$ mA, $t_p = 20$ ms	$2.1 (\leq 2.8)$	$I_F = 50$ mA, $t_p = 20$ ms	100	Q62702P5053	66
 TO 18	SFH 4850 E7800	850	± 23	$7 (> 4)$	$I_F = 100$ mA, $t_p = 20$ ms	$1.5 (\leq 1.8)$	$I_F = 100$ mA, $t_p = 20$ ms	12	Q65110A2093	34
 TO 18	SFH 480	880	± 6	> 40	$I_F = 100$ mA, $t_p = 20$ ms	$1.5 (\leq 1.8)$	$I_F = 100$ mA, $t_p = 20$ ms	600	Q62703Q1087	42
	SFH 480-2/3								Q62702P5195	
 TO 18	SFH 483 L/M E7800	880	± 23	$2 (1 \dots 3.2)$	$I_F = 100$ mA, $t_p = 20$ ms	$1.5 (\leq 1.8)$	$I_F = 100$ mA, $t_p = 20$ ms	600	Q62703Q4755	34
 TO 18	SFH 482	880	± 30	> 3.15	$I_F = 100$ mA, $t_p = 20$ ms	$1.5 (\leq 1.8)$	$I_F = 100$ mA, $t_p = 20$ ms	600	Q62703Q1089	43
	SFH 482-1/2			$3.15 \dots 10$					Q62703Q4771	
	SFH 482-2/3			> 5					Q62703Q4754	
	SFH 482 M E7800			$1.6 \dots 3.2$					Q62703Q2186	
 TO 46	SFH 4881	880	± 5	$72 (> 40)$	$I_F = 100$ mA, $t_p = 20$ ms	$1.5 (\leq 1.8)$	$I_F = 100$ mA, $t_p = 20$ ms	500	Q62702P5302	74
 TO 46	SFH 4883	880	± 35	$8 (> 4)$	$I_F = 100$ mA, $t_p = 20$ ms	$1.5 (\leq 1.8)$	$I_F = 100$ mA, $t_p = 20$ ms	500	Q62702P5303	75
 TO 18	LD 242 E7800	950	± 40	$1 \dots 3.2$	$I_F = 100$ mA, $t_p = 20$ ms	$1.3 (\leq 1.5)$	$I_F = 100$ mA, $t_p = 20$ ms	1000	Q62703Q3509	34
	LD 242-2/3			> 4					Q62703Q4749	

Infrared Emitters | IR-Lumineszenzdioden

Package Gehäuse	Type Bezeichnung	λ_{peak} typ [nm]	Half angle φ [°]					t_r, t_f typ [ns]	Ordering Code Bestellnummer	Package Fig. Bauteilzeich- nung
				I_e [mW/sr]	Measure- ment cond.	V_F [V]	Measure- ment cond.			
 TO 18	SFH 400	950	± 6	> 20	$I_F = 100$ mA, $t_p = 20$ ms	$1.3 (\leq 1.5)$	$I_F = 100$ mA, $t_p = 20$ ms	1000	Q62702P0096	42
 TO 18	SFH 401	950	± 15	> 10	$I_F = 100$ mA, $t_p = 20$ ms	$1.3 (\leq 1.5)$	$I_F = 100$ mA, $t_p = 20$ ms	1000	Q62702P0097	69
	SFH 4811	950	± 5	$40 (> 25)$	$I_F = 100$ mA, $t_p = 20$ ms	≤ 1.5	$I_F = 20$ mA	1000	Q62702P5300	74
	SFH 4813	950	± 35	$4.5 (> 2.5)$	$I_F = 100$ mA, $t_p = 20$ ms	≤ 1.5	$I_F = 20$ mA	1000	Q62702P5301	75

Silicon Photodetectors, Optical Sensors and Infrared Emitters

| Si-Fotodetektoren, Optische Sensoren und IR-Lumineszenzdioden

Outline drawings - Dimensions in mm (inch) | Outline drawings - Dimensions in mm (inch)

Figure 1: SFH 5110

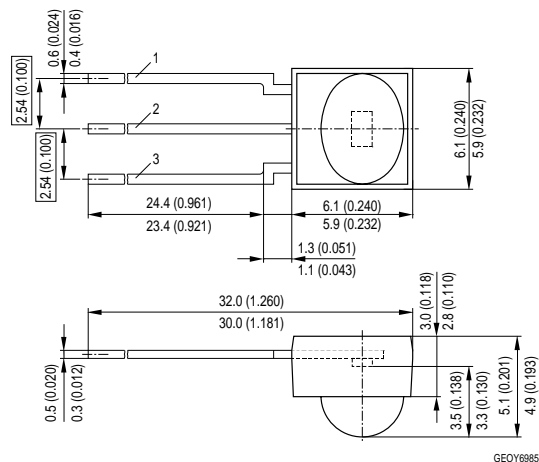


Figure 2: SFH 320, SFH 320 FA

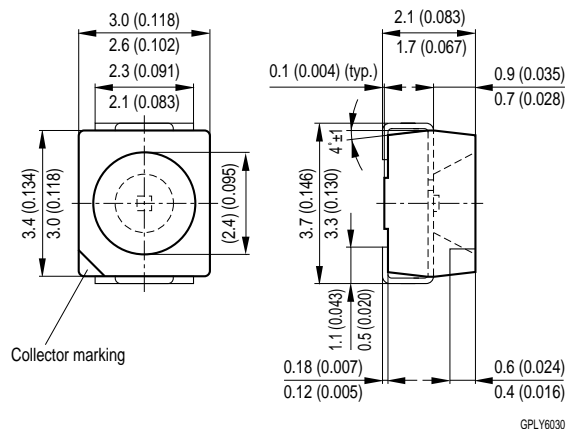


Figure 3: SFH 3211, SFH 3211 FA

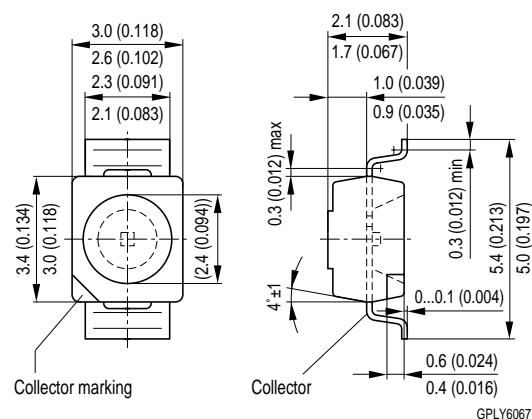


Figure 4: SFH 325, SFH 325 FA,

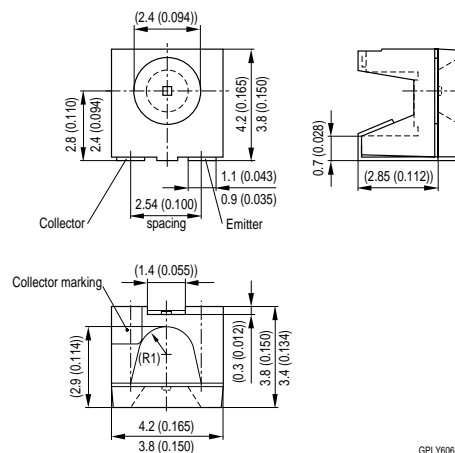


Figure 5: SFH 331, SFH 7225

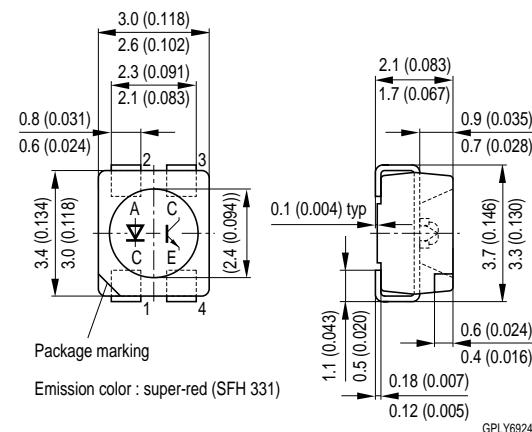
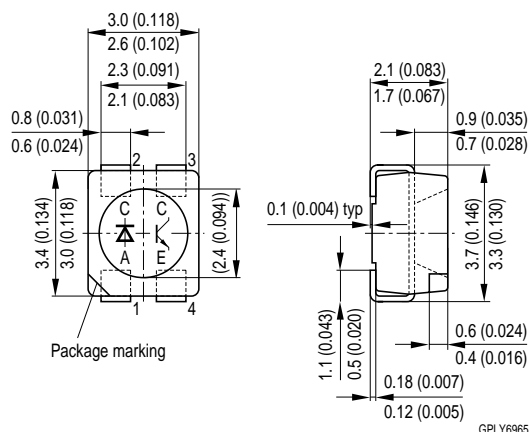


Figure 6: SFH 7221

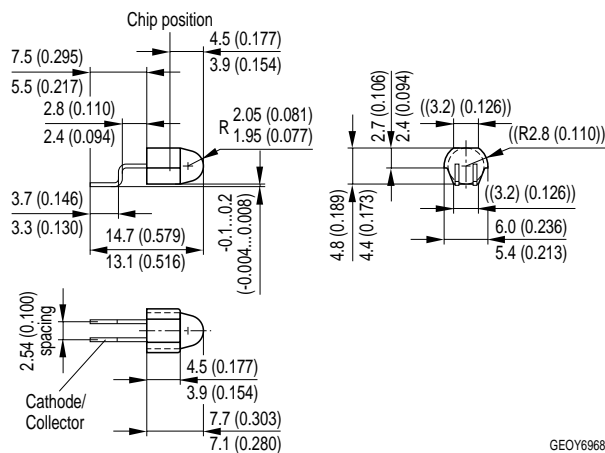


Silicon Photodetectors, Optical Sensors and Infrared Emitters

| Si-Fotodetektoren, Optische Sensoren und IR-Lumineszenzdiolen

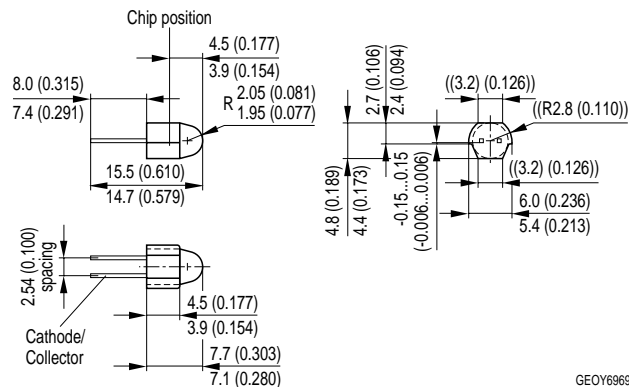
Outline drawings - Dimensions in mm (inch) | Outline drawings - Dimensions in mm (inch)

Figure 7: SFH 3500, SFH 3500 FA, SFH 2500 FA, SFH 4510



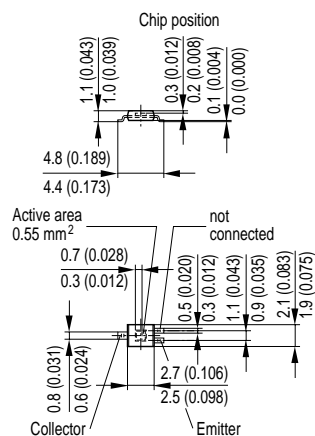
GEOY6968

Figure 8: SFH 3505, SFH 3505 FA, SFH 2505, SFH 2505 FA SFH 4515



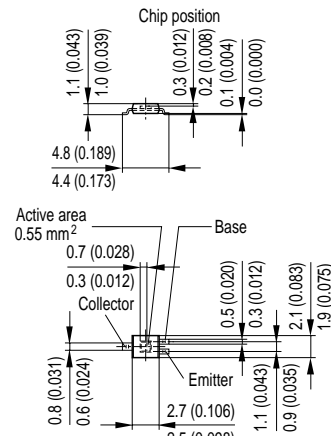
GEOY6969

Figure 9: SFH 3400



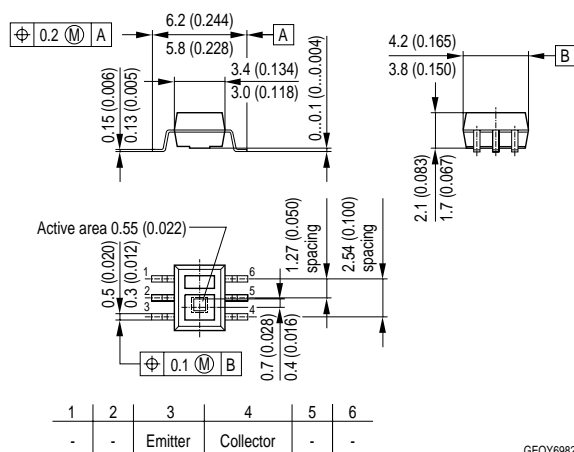
GEOY6953

Figure 10: SFH 3401



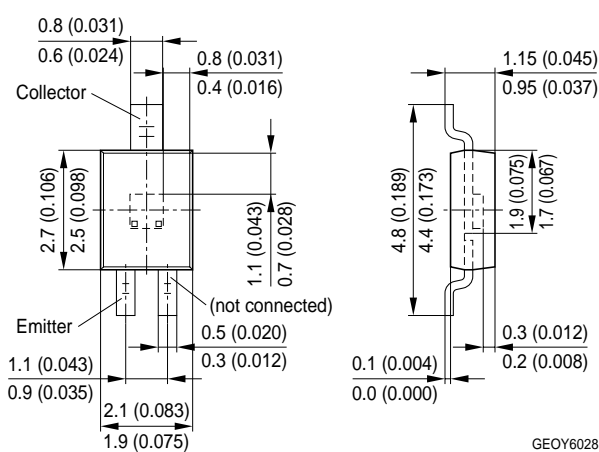
GEOY6973

Figure 11: SFH 3201



GEOY6982

Figure 12: SFH 3410



GEOY6028

Silicon Photodetectors, Optical Sensors and Infrared Emitters

| Si-Fotodetektoren, Optische Sensoren und IR-Lumineszenzdioden

Outline drawings - Dimensions in mm (inch) | Outline drawings - Dimensions in mm (inch)

Figure 13: BP 104 FS, BP 104 S, BP 104 FAS

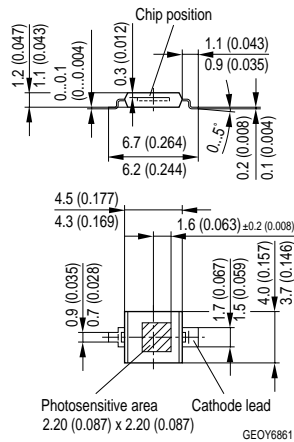


Figure 14: BPW 34 S, BPW 34 FS, BPW 34 FAS, BPW 34 BS

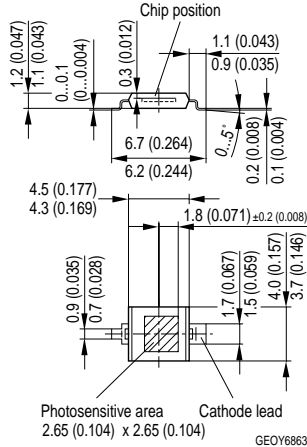


Figure 15: BPW 34 SR, BPW 34 FASR, BPW 34 FSR

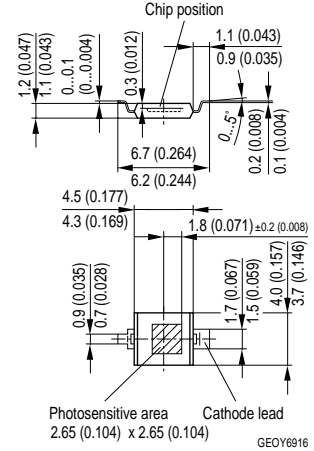


Figure 16: SFH 2400, SFH 2400 FA

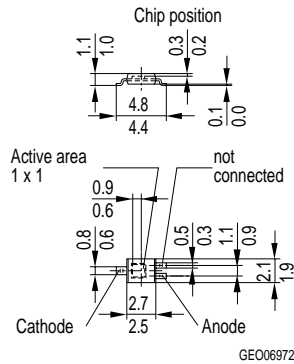


Figure 17: KOM 2125, KOM 2125 FA

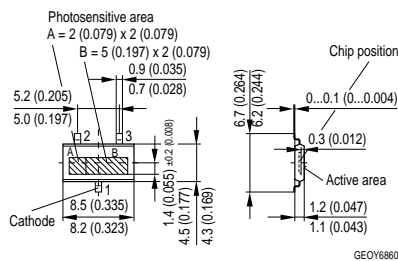


Figure 18: SFH 5440

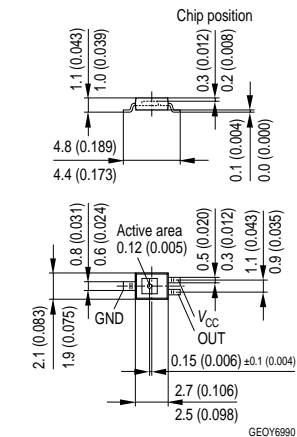


Figure 19: SFH 5140 F

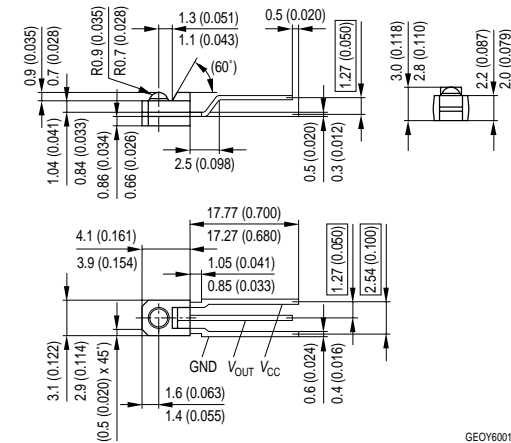
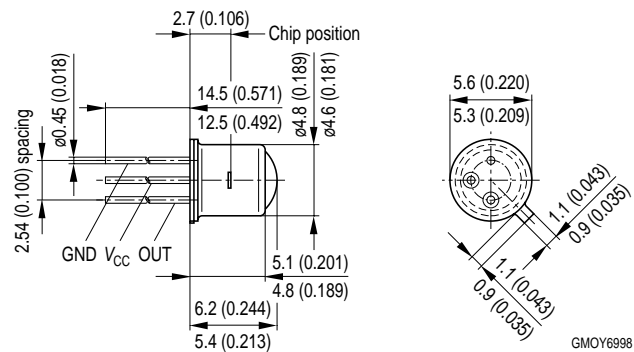


Figure 20: SFH 5840



Silicon Photodetectors, Optical Sensors and Infrared Emitters

| Si-Fotodetektoren, Optische Sensoren und IR-Lumineszenzdioden

Outline drawings - Dimensions in mm (inch) | Outline drawings - Dimensions in mm (inch)

Figure 21: BP 104 FASR

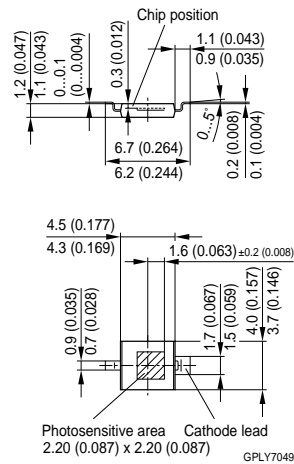


Figure 22: SFH 309, SFH 309 FA, SFH 229, SFH 229 FA

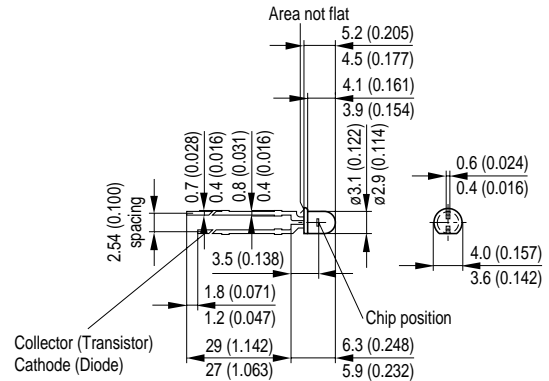


Figure 23: SFH 310, SFH 310 FA

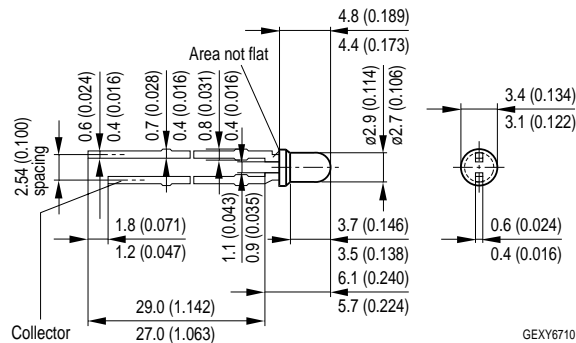


Figure 24: SFH 309 P, SFH 309 PFA

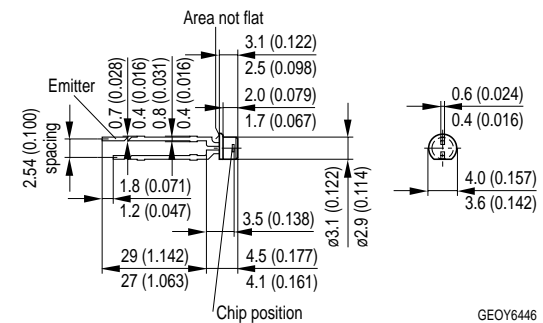


Figure 25: SFH 313, SFH 313 FA SFH 213, SFH 213 FA

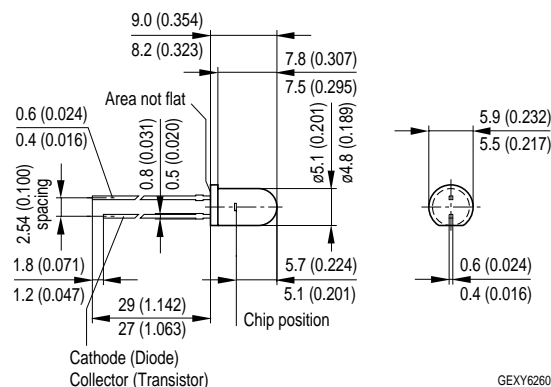
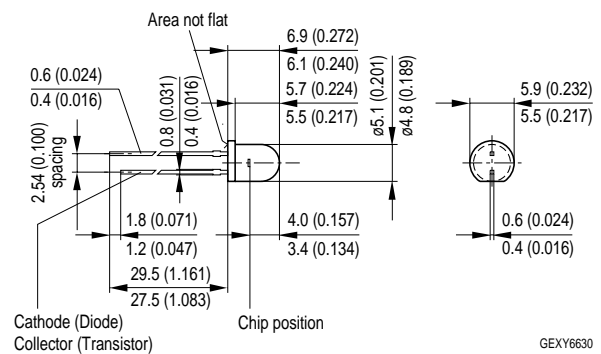


Figure 26: SFH 314, SFH 314 FA



Silicon Photodetectors, Optical Sensors and Infrared Emitters

| Si-Fotodetektoren, Optische Sensoren und IR-Lumineszenzdioden

Outline drawings - Dimensions in mm (inch) | Outline drawings - Dimensions in mm (inch)

Figure 27: SFH 303, SFH 303 FA

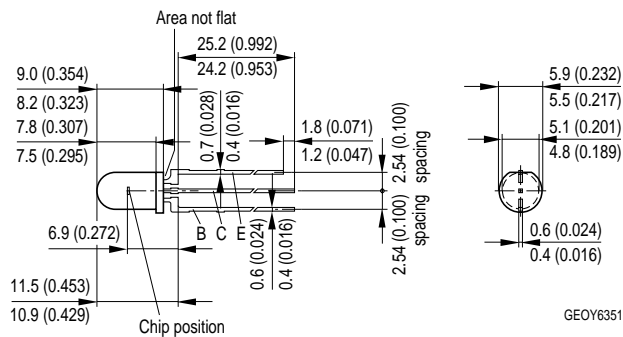


Figure 28: LPT 80 A

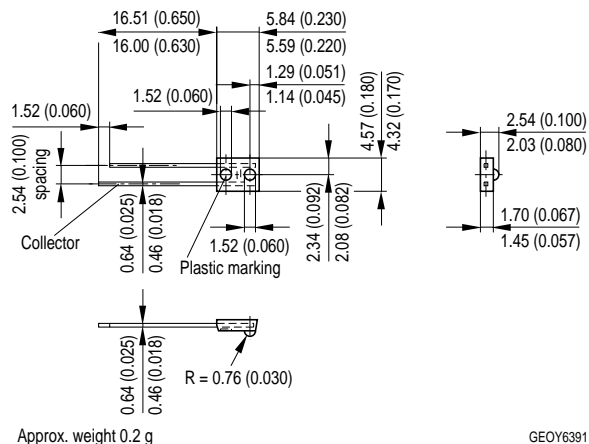


Figure 29: SFH 3100 F, SFH 4110

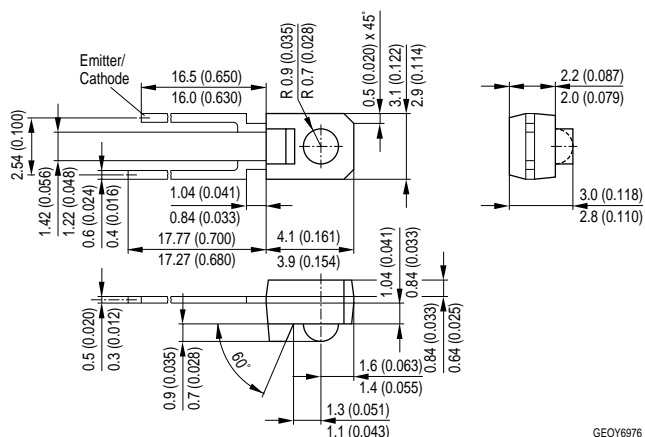


Figure 30: BPX 43, BPY 62

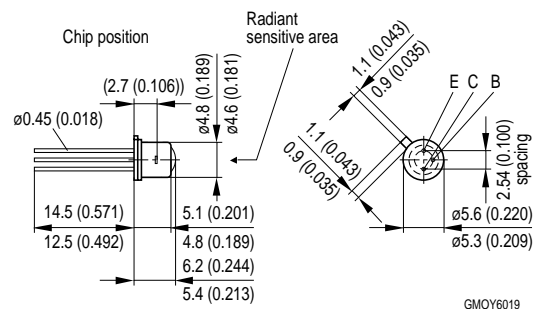


Figure 31: SFH 305, SFH 405

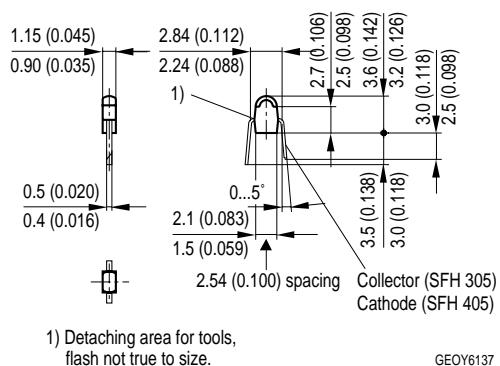


Figure 32: BPX 81, LD 261

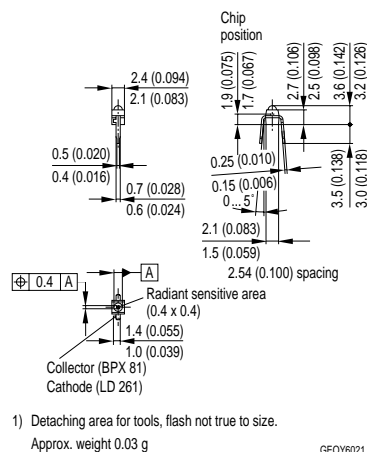


Figure 33: BPX 80, BPX 82-89, LD 260, LD 262-269

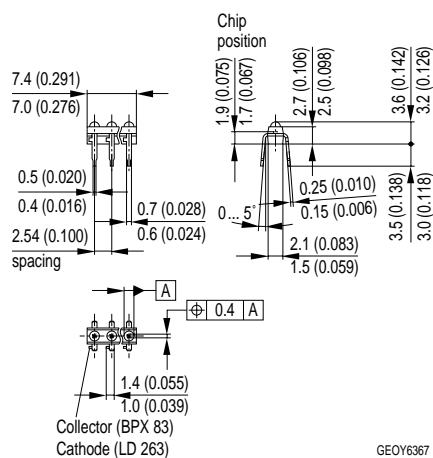


Figure 34: SFH 4850, SFH 464, LD 242, SFH 483

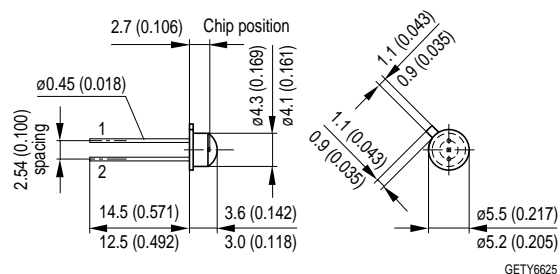


Figure 35: SFH 206 K

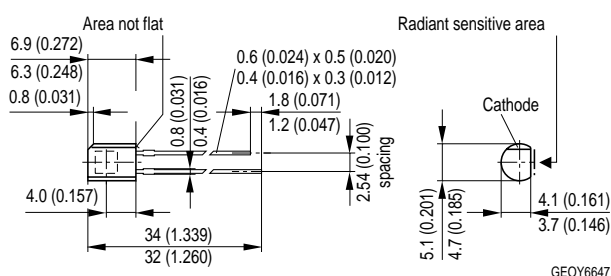


Figure 36: SFH 203, SFH 203 FA, LD 271 L/LH, SFH 415, SFH 4511

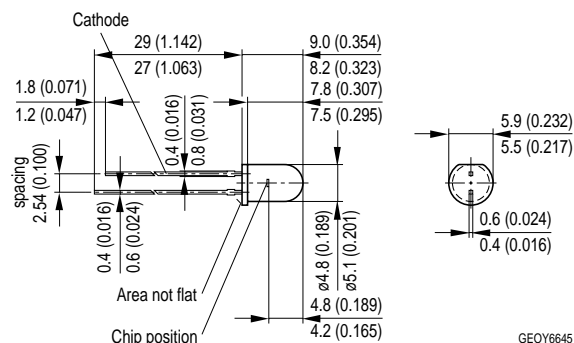


Figure 37: SFH 203 P, SFH 203 PFA

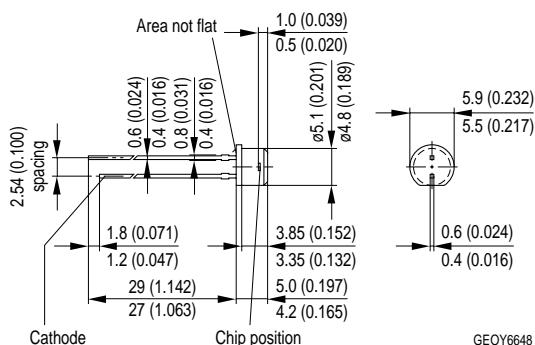
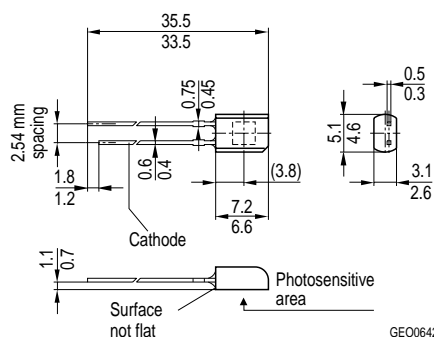


Figure 38: SFH 225 FA, SFH 235 FA



Silicon Photodetectors, Optical Sensors and Infrared Emitters

| Si-Fotodetektoren, Optische Sensoren und IR-Lumineszenzdioden

Outline drawings - Dimensions in mm (inch) | Outline drawings - Dimensions in mm (inch)

Figure 39: SFH 205 F, SFH 205 FA

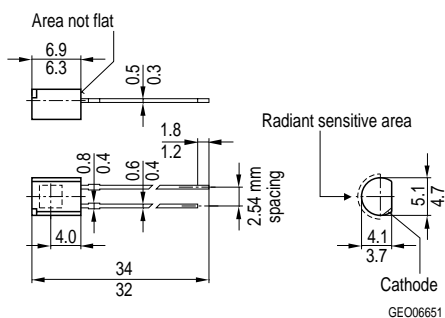


Figure 40: SFH 204 FA

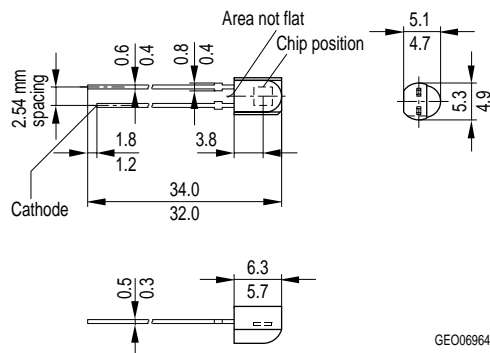


Figure 41: BP 104 F

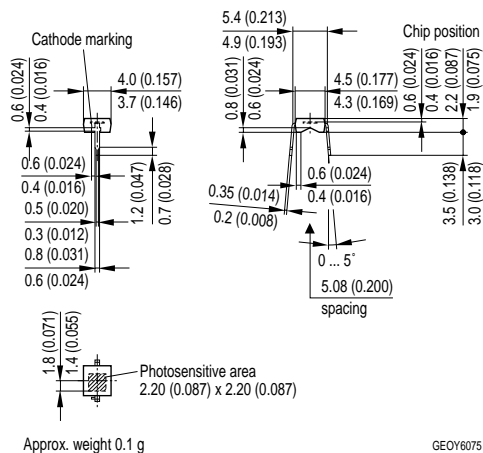


Figure 42: SFH 400, SFH 480

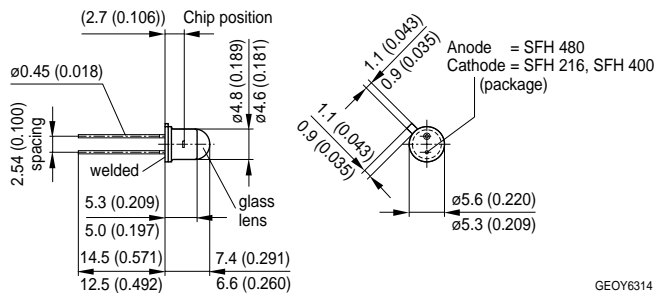


Figure 43: SFH 482, BPX 65

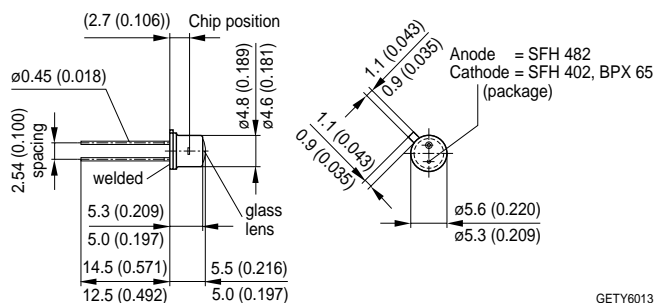
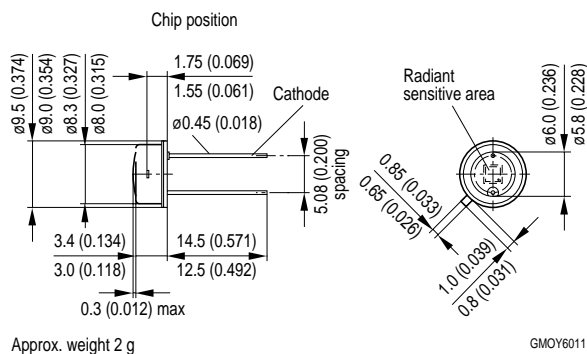


Figure 44: BPW 21, BPX 61



Silicon Photodetectors, Optical Sensors and Infrared Emitters

| Si-Fotodetektoren, Optische Sensoren und IR-Lumineszenzdioden

Outline drawings - Dimensions in mm (inch) | Outline drawings - Dimensions in mm (inch)

Figure 45: SFH 221

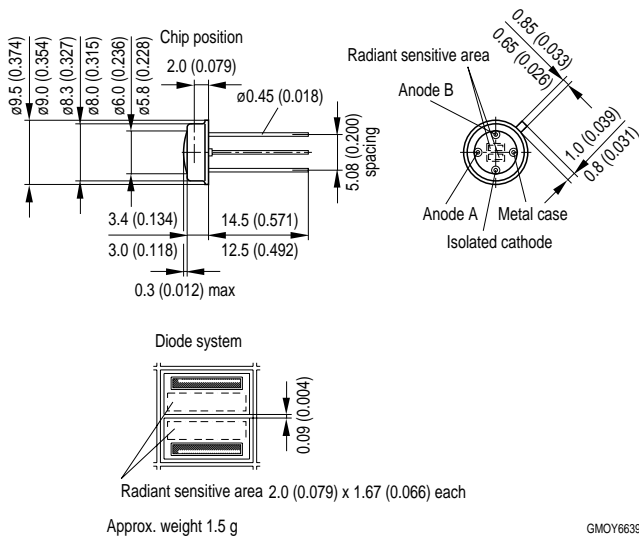


Figure 46: BPX 48

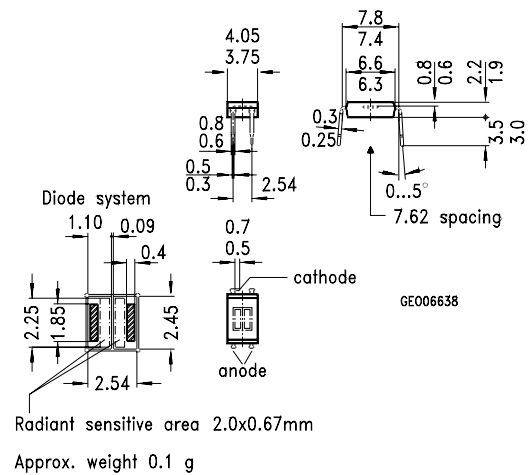


Figure 47: SFH 9315

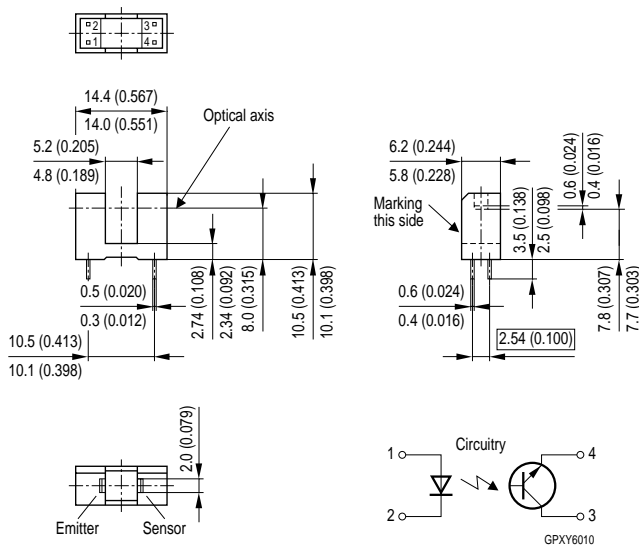
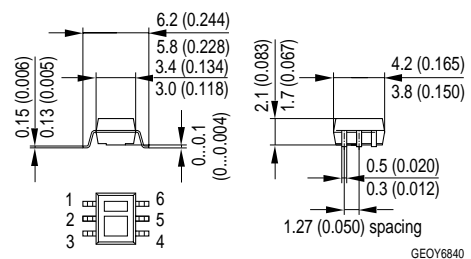


Figure 48: SFH 9201, SFH 9202, SFH 9240



Outline drawings - Dimensions in mm (inch) | Outline drawings - Dimensions in mm (inch)

Figure 1 consists of two mechanical drawings. The top drawing is a side view of a chip position, showing a rectangular chip with a circular feature. Dimensions are given in mm and inches. The bottom drawing is a top view of a chip carrier, showing a rectangular carrier with a circular feature. Dimensions are given in mm and inches. The chip carrier drawing includes a 'Cathode' label and a 'spacing' dimension.

Chip position dimensions (mm/inch):

- 7.5 (0.295)
- 5.5 (0.217)
- 2.8 (0.110)
- 2.4 (0.094)
- 3.7 (0.146)
- 3.3 (0.130)
- 14.7 (0.579)
- 13.1 (0.516)
- 4.5 (0.177)
- 3.9 (0.154)
- 2.05 (0.081)
- 1.95 (0.077)
- R 0.1 (0.004)
- 0.1...0.2 (-0.004...0.008)

Chip carrier dimensions (mm/inch):

- 2.54 (0.100) spacing
- 4.5 (0.177)
- 3.9 (0.154)
- 7.7 (0.303)
- 7.1 (0.280)
- 4.8 (0.189)
- 4.4 (0.173)
- 2.7 (0.106)
- 2.4 (0.094)
- 3.2 (0.126)
- 3.2 (0.126)
- 6.0 (0.236)
- 5.4 (0.213)
- R2.8 (0.110)

Figure 1 shows the dimensions of the package. The top view (left) and side view (right) are provided. The top view dimensions are:

- Overall width: 3.0 (0.118)
- Pin 1 to Pin 2 distance: 2.6 (0.102)
- Pin 2 to Pin 3 distance: 2.3 (0.091)
- Pin 3 to Pin 4 distance: 2.1 (0.083)
- Pin 4 to Pin 1 distance: 0.8 (0.031)
- Pin 1 to Pin 3 distance: 0.6 (0.024)
- Pin 2 to Pin 4 distance: 0.6 (0.024)
- Die width: 3.4 (0.134)
- Die height: 3.0 (0.118)
- Die mounting pad width: 2.4 (0.094)
- Die mounting pad height: 0.1 (0.004) typ

The side view dimensions are:

- Overall height: 3.7 (0.146)
- Die height: 3.3 (0.130)
- Pin 1 to Pin 2 distance: 0.9 (0.035)
- Pin 2 to Pin 3 distance: 0.7 (0.028)
- Pin 3 to Pin 4 distance: 0.6 (0.024)
- Pin 4 to Pin 1 distance: 0.4 (0.016)
- Pin 1 to Pin 3 distance: 1.1 (0.043)
- Pin 2 to Pin 4 distance: 0.5 (0.020)
- Pin 1 to Pin 4 distance: 0.18 (0.007)
- Pin 2 to Pin 3 distance: 0.12 (0.005)

Silicon Photodetectors, Optical Sensors and Infrared Emitters

| Si-Fotodetektoren, Optische Sensoren und IR-Lumineszenzdiolen

Outline drawings - Dimensions in mm (inch) | Outline drawings - Dimensions in mm (inch)

Figure 55: SFH 487, SFH 4301, SFH 409, SFH 4350

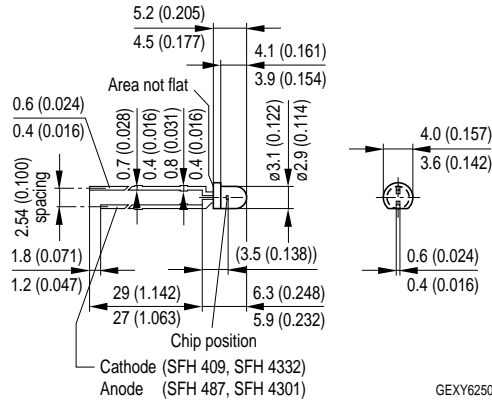


Figure 56: SFH 4501

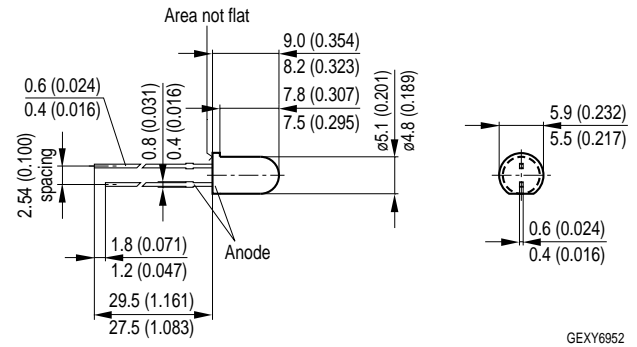


Figure 57: SFH 4502

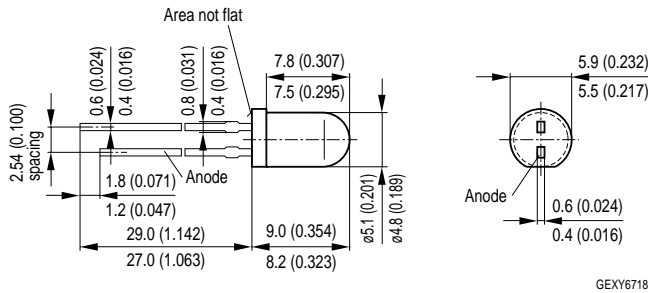


Figure 58: SFH 4503

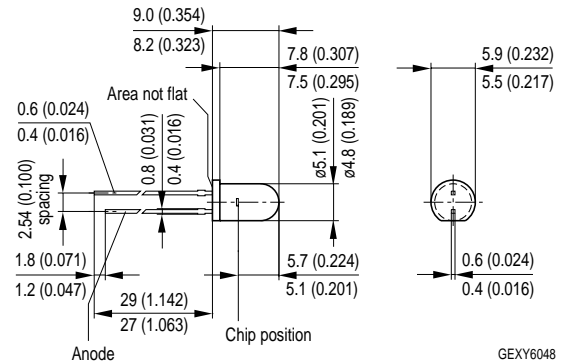


Figure 59: IRL 80 A, IRL 81 A

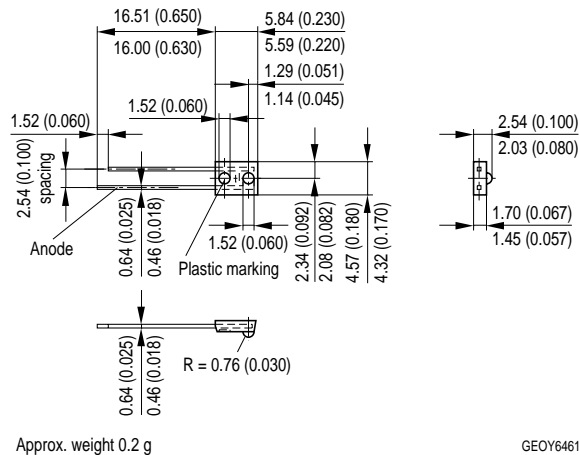
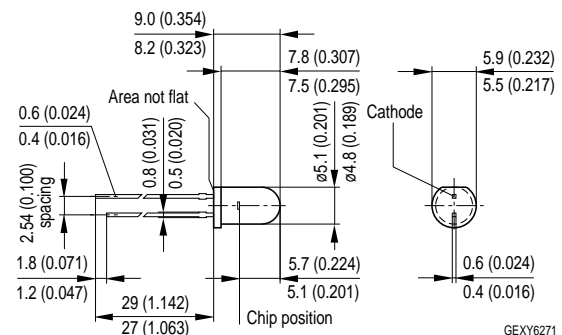


Figure 60: SFH 484, SFH 4550



Silicon Photodetectors, Optical Sensors and Infrared Emitters

| Si-Fotodetektoren, Optische Sensoren und IR-Lumineszenzdioden

Outline drawings - Dimensions in mm (inch) | Outline drawings - Dimensions in mm (inch)

Figure 61: SFH 485

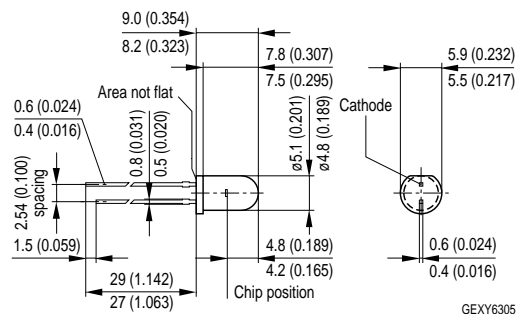


Figure 62: SFH 486

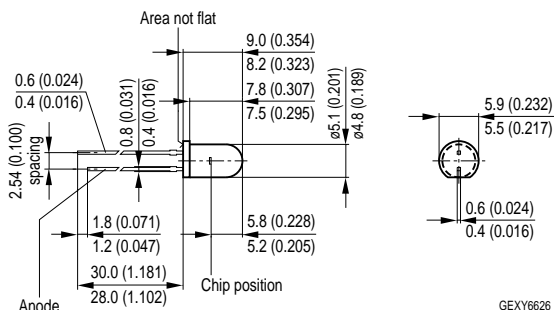


Figure 63: SFH 485 P

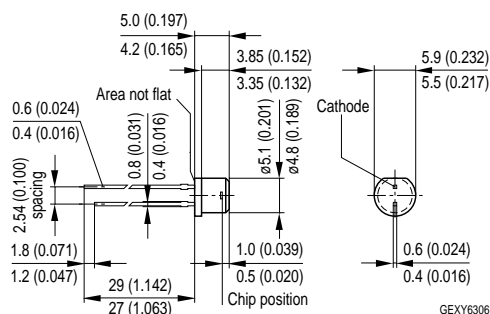


Figure 64: SFH 487 P

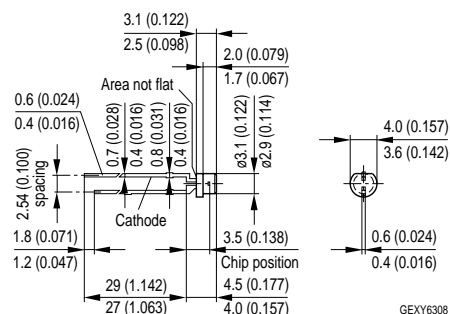


Figure 65: LD 274

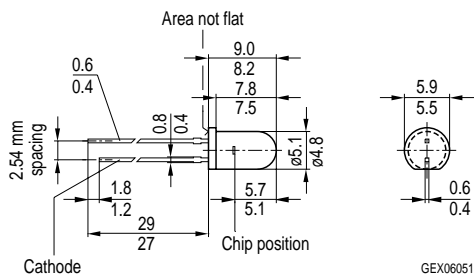


Figure 66: SFH 4860

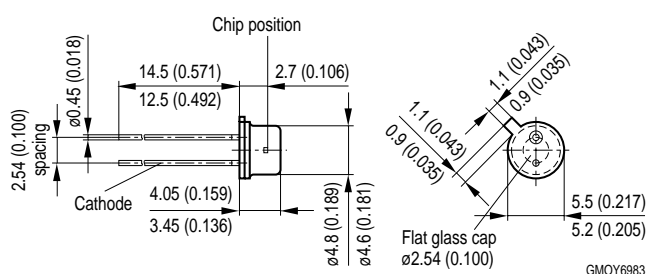


Figure 67: BPX 38

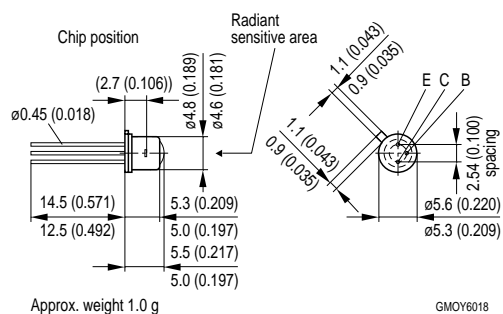
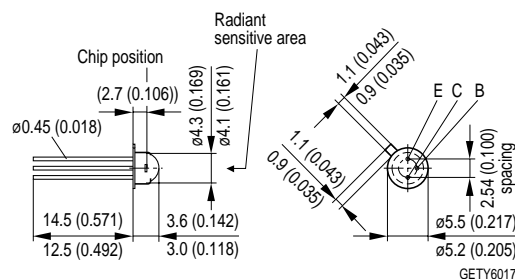


Figure 68: BP 103



Silicon Photodetectors, Optical Sensors and Infrared Emitters

| Si-Fotodetektoren, Optische Sensoren und IR-Lumineszenzdiode

Outline drawings - Dimensions in mm (inch) | Outline drawings - Dimensions in mm (inch)

Figure 69: SFH 401

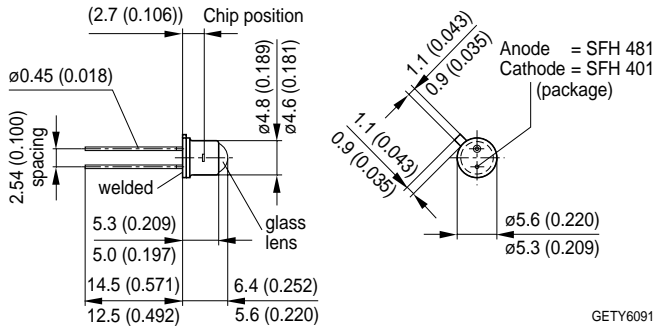


Figure 70: SFH 4281

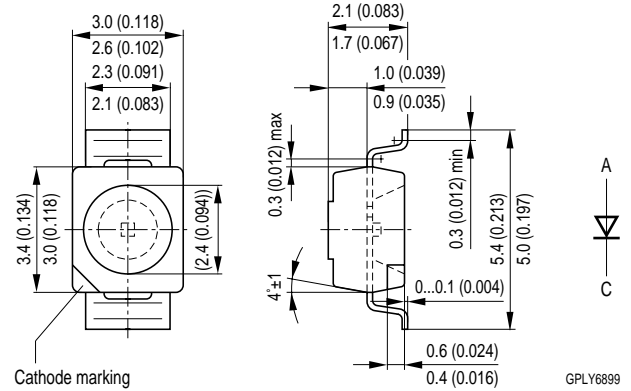


Figure 71: SFH 425, SFH 426, SFH 4205, SFH 4255

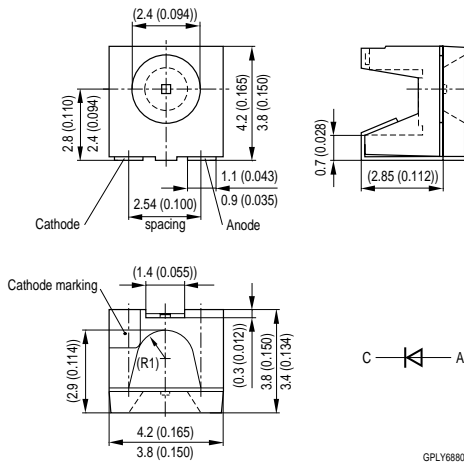


Figure 72: SFH 4250

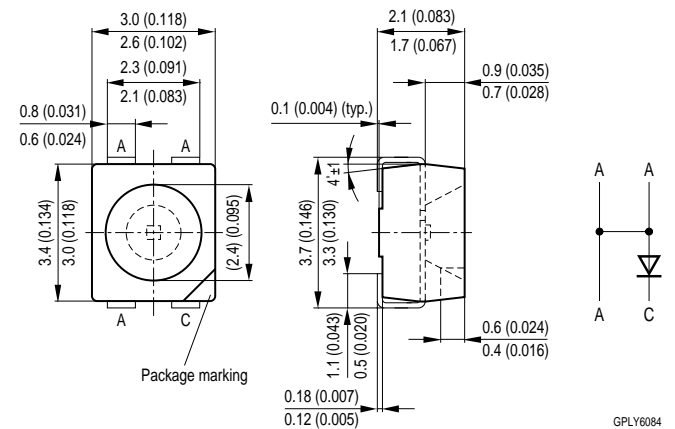


Figure 73: SFH 4259

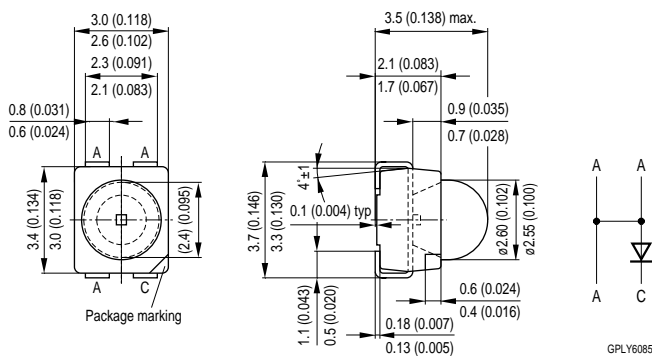
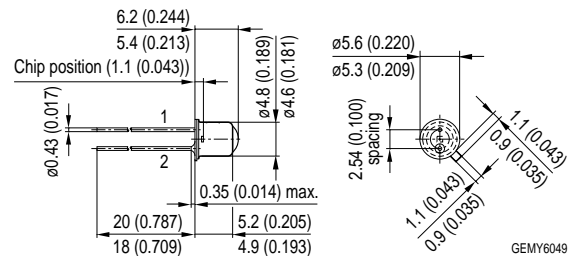


Figure 74: SFH 4881, SFH 4811



Silicon Photodetectors, Optical Sensors and Infrared Emitters

| Si-Fotodetektoren, Optische Sensoren und IR-Lumineszenzdioden

Outline drawings - Dimensions in mm (inch) | Outline drawings - Dimensions in mm (inch)

Figure 75: SFH 4883, SFH 4813

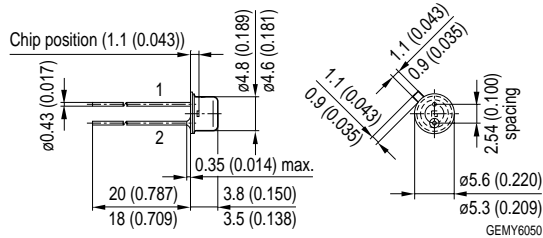


Figure 76: SFH 7740, SFH 7741

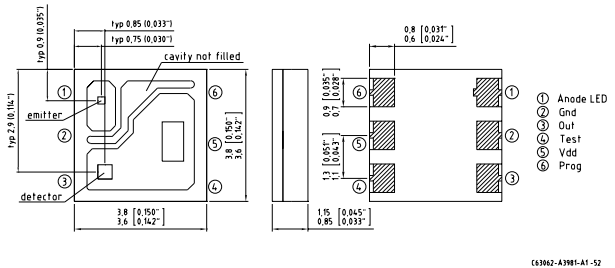


Figure 77: SFH 5130

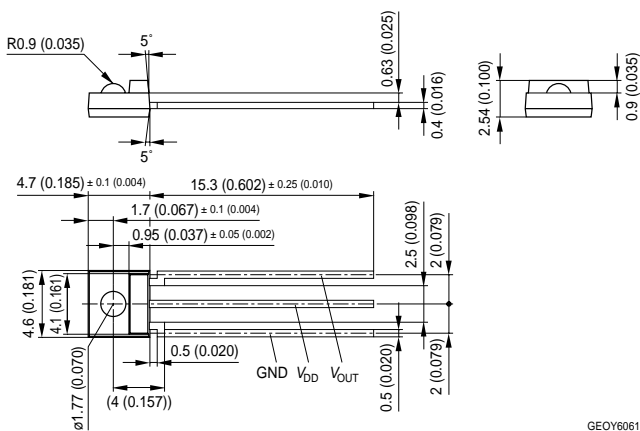


Figure 78: SFH 5410

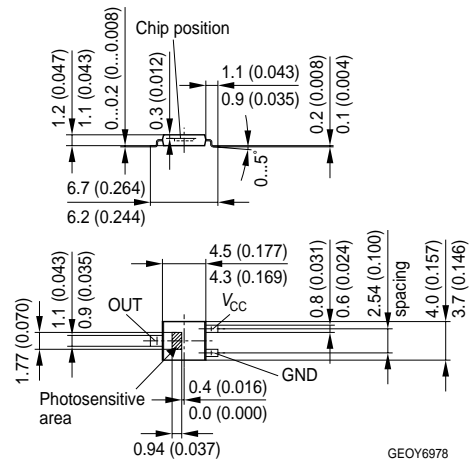


Figure 79: SFH 420, SFH 421, SFH 4200, SFH 4211, SFH 4252, SFH 4272, SFH 4273

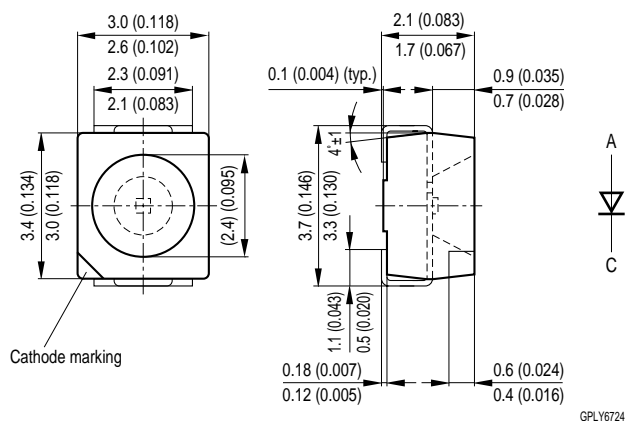
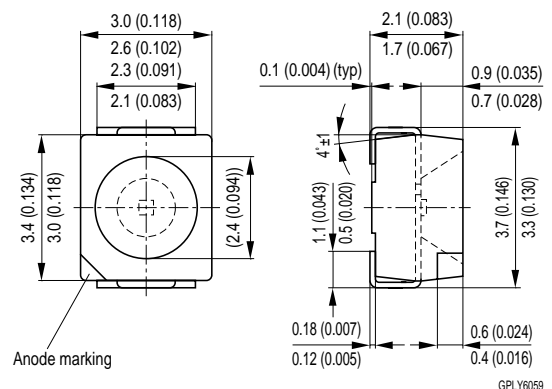


Figure 80: SFH 4271, SFH 4257



Silicon Photodetectors, Optical Sensors and Infrared Emitters

| Si-Fotodetektoren, Optische Sensoren und IR-Lumineszenzdiolen

Outline drawings - Dimensions in mm (inch) | Outline drawings - Dimensions in mm (inch)

Figure 81: SFH 3204

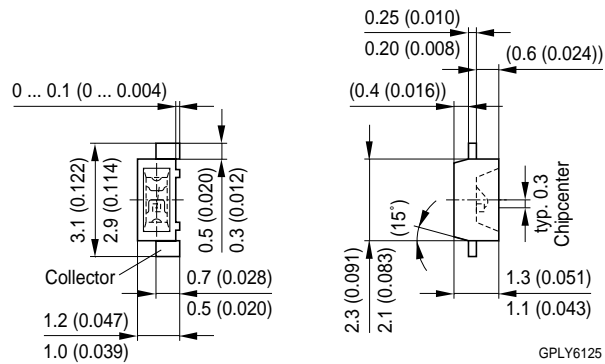


Figure 82: SFH 300, SFH 300 FA

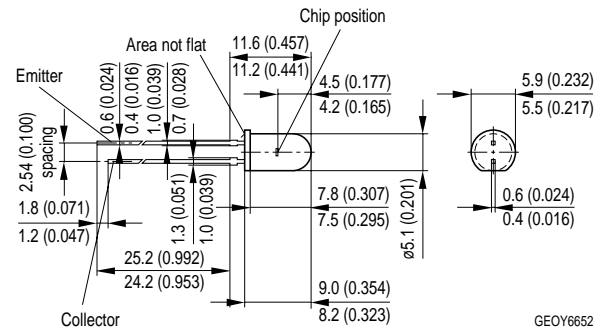


Figure 83: SFH 2430

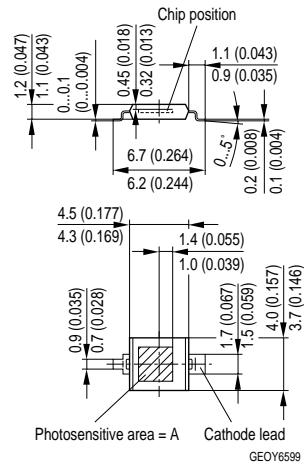


Figure 84: BPW 34, BPW 34 F, BPW 34 B, BPW 34 FA

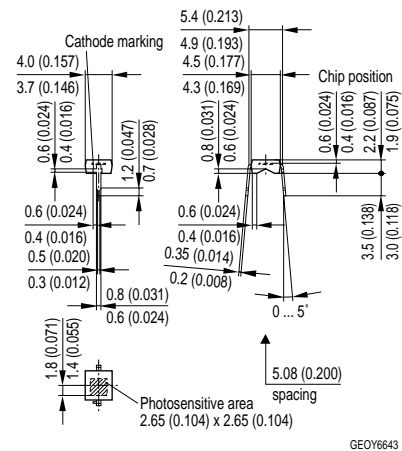


Figure 85: SFH 4258

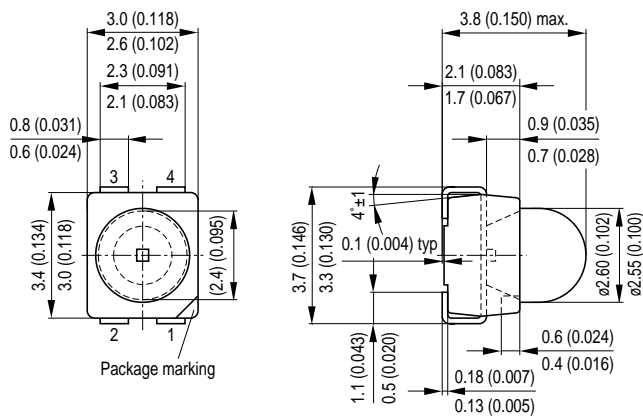
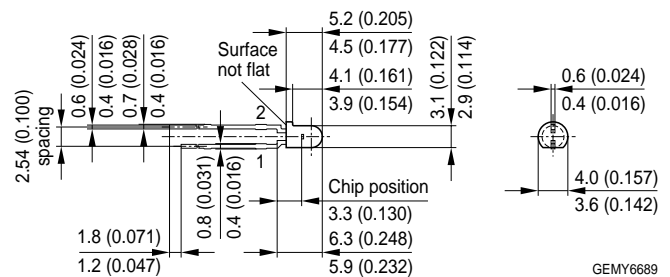
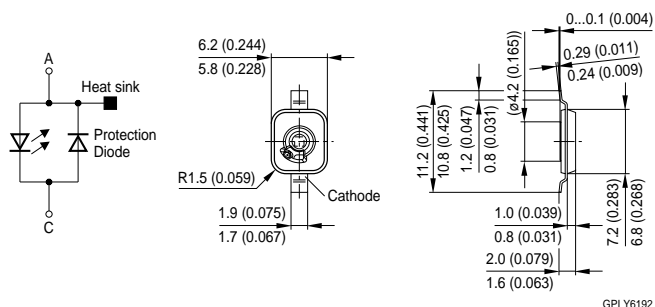
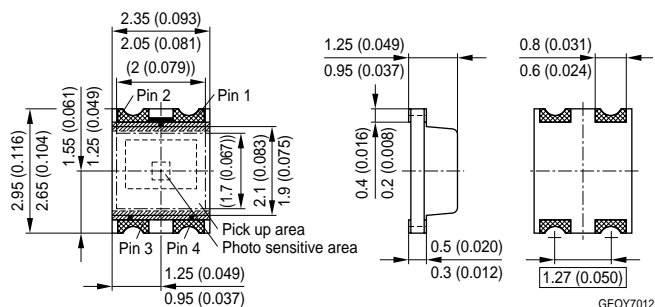
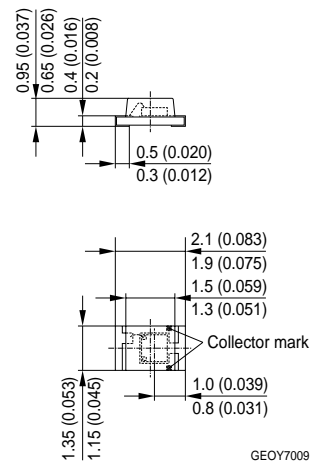
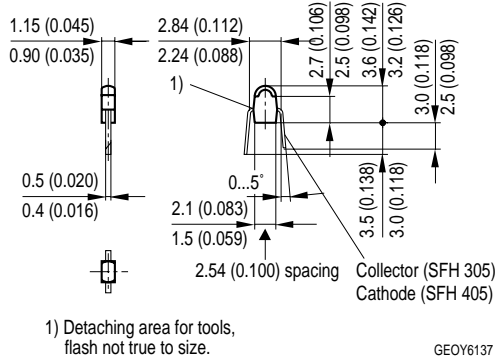
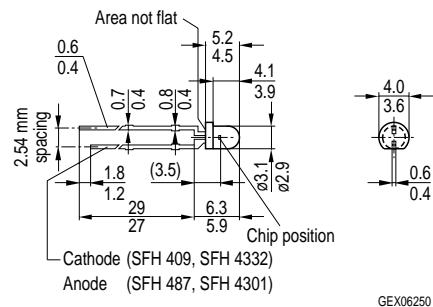
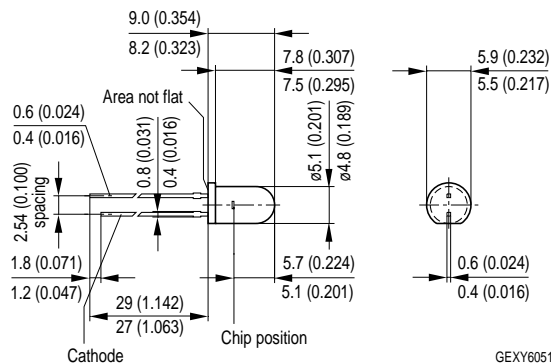


Figure 86: SFH 4350



Outline drawings - Dimensions in mm (inch) | Outline drawings - Dimensions in mm (inch)



Outline drawings - Dimensions in mm (inch) | Outline drawings - Dimensions in mm (inch)

[illegible]

GEXY6239

Technical drawing of a cathode assembly. The drawing includes a side view and a cross-sectional view. Dimensions are provided in millimeters (mm) and inches (in).

Side View Dimensions:

- Top surface: 29 (1.142), 27 (1.063)
- Right side: 9.0 (0.354), 8.2 (0.323), 7.8 (0.307), 7.5 (0.295)
- Left side: 1.8 (0.071), 1.2 (0.047)
- Bottom left: 2.54 (0.100)
- Internal features: 0.4 (0.016), 0.8 (0.031), 0.4 (0.016), 0.6 (0.024)
- Bottom right: 4.8 (0.189), 4.2 (0.165)
- Bottom center: 4.8 (0.189), 4.2 (0.165)
- Bottom left: 0.4 (0.016), 0.6 (0.024)

Cross-sectional View Dimensions:

- Top: 5.9 (0.232), 5.5 (0.217)
- Bottom: 0.6 (0.024), 0.4 (0.016)

Labels:

- Cathode
- Area not flat
- Chip position

Scale: 1:1

GEOY6645

Figure 1: Dimensions of the test specimen. The figure shows two views of a rectangular specimen with a central hole. The top view (left) shows a square hole with a side length of 3.05 (0.120) mm. The hole is centered, with a distance of 3.35 (0.132) mm from the center to the top and bottom edges. The hole has a radius of 0.9 (0.035) mm. The distance from the center of the hole to the top and bottom edges of the specimen is 1.65 (0.065) mm. The distance from the center of the hole to the left and right edges of the specimen is 1.35 (0.053) mm. The bottom view (right) shows a rectangular hole with a width of 0.7 (0.028) mm and a height of 0.4 (0.016) mm. The hole is centered, with a distance of 0.9 (0.035) mm from the center to the top and bottom edges. The distance from the center of the hole to the left and right edges of the specimen is 1.25 (0.049) mm. The distance from the center of the hole to the top and bottom edges of the specimen is 0.92 (0.036) mm. The distance from the center of the hole to the left and right edges of the specimen is 2.15 (0.085) mm. The distance from the center of the hole to the top and bottom edges of the specimen is 1.85 (0.073) mm. The center of the active area is marked with a crosshair.

GPLY7034

GPLY7039

¹⁾ Device casted with silicone.
Avoid mechanical stress on silicone surface.

QHF02956

GPXY698

Silicon Photodetectors, Optical Sensors and Infrared Emitters

| Si-Fotodetektoren, Optische Sensoren und IR-Lumineszenzdioden

Outline drawings - Dimensions in mm (inch) | Outline drawings - Dimensions in mm (inch)

Figure 99: SFH 4730, SFH 4740

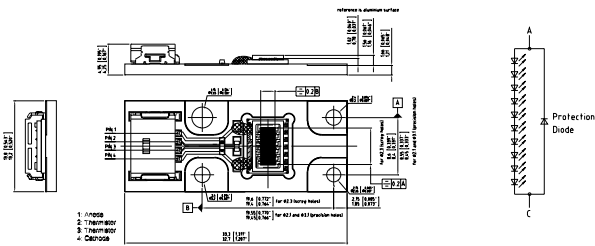


Figure 100: SFH 4556

